

Numerical study of the influence of ion-induced electrons on the dynamics of electron clouds in gyrotron-like geometries

S. Guinchard¹, G. Le Bars²

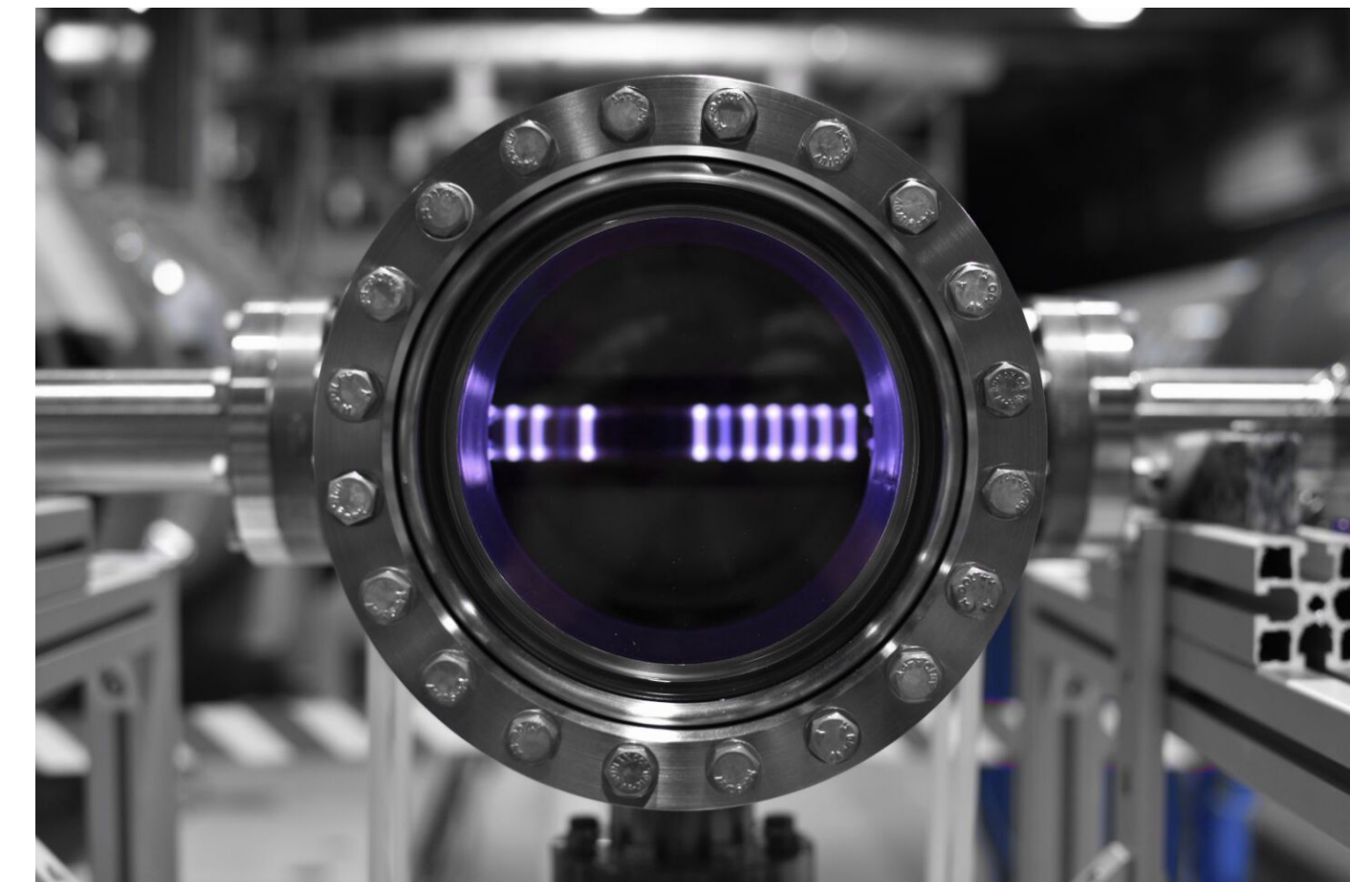
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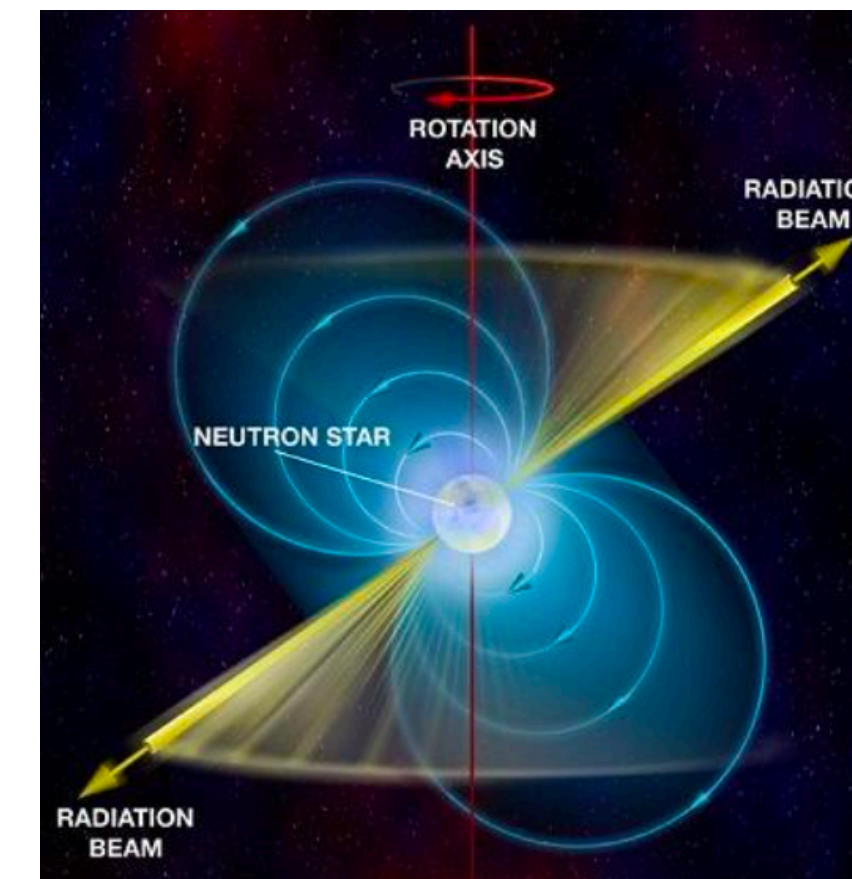
² Ecole Polytechnique Fédérale de Lausanne (EPFL), Swiss Plasma Center (SPC), CH-1015 Lausanne, Switzerland

- Introduction
- II - Theory
 - Choosing a model
 - Implementation
- III - Results
 - Module testing
 - Cloud formation and dynamics
 - TREX *slanted*
 - TREX *extrude*
 - GT-170
- Conclusion

- Collection of charged parts s.t. overall no charge neutrality [DS]
- Non-neutral plasmas relevant to many fields of physics: Astrophysics, atomic clocks, particle accelerators, surface engineering & **ECRH**.
- Electron Cyclotron Resonant Heating, for which **gyrotrons** are needed.



C sputtering in a plasma cell [Cern]



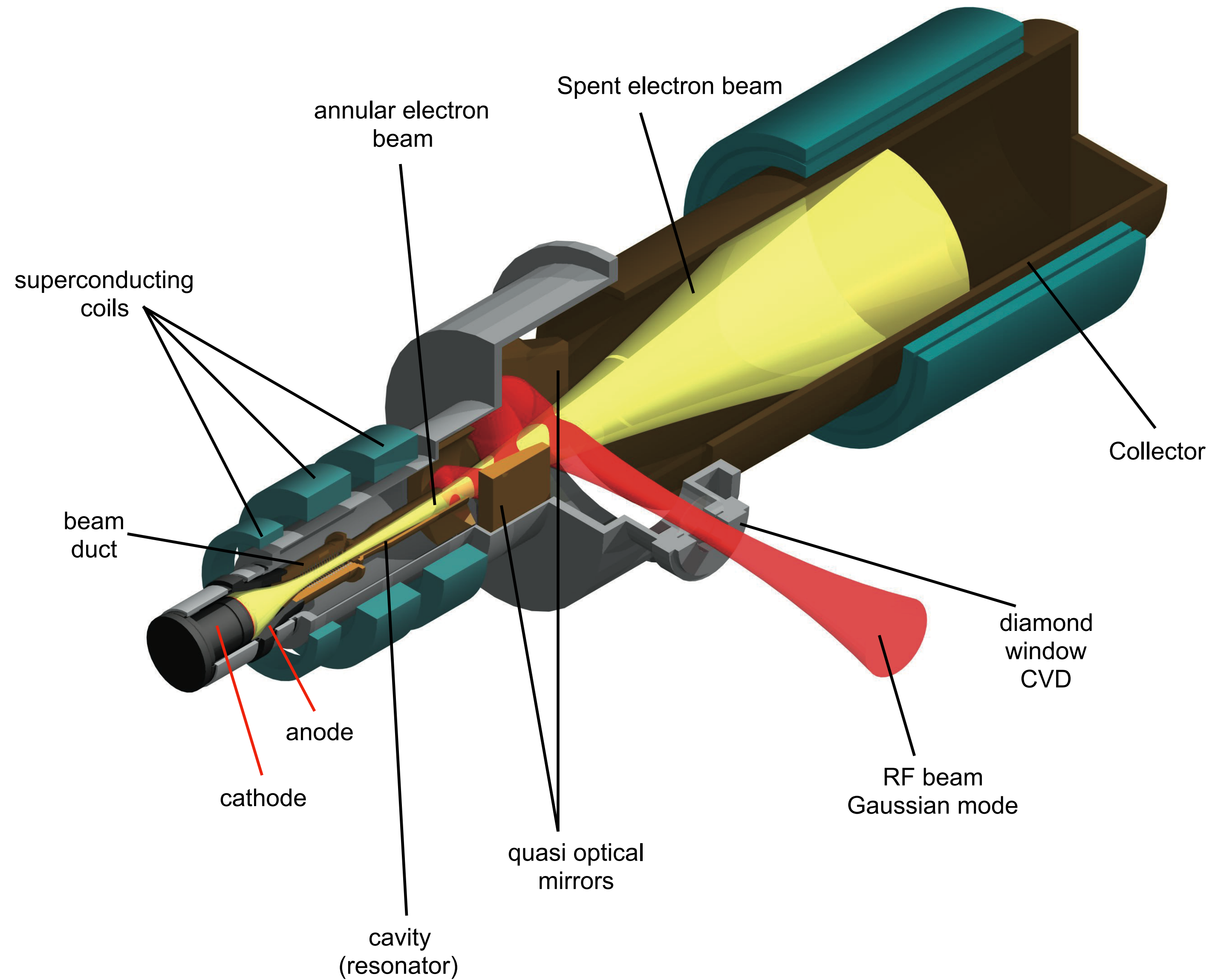
Neutron star magnetosphere



TCV gyrotron for ECRH

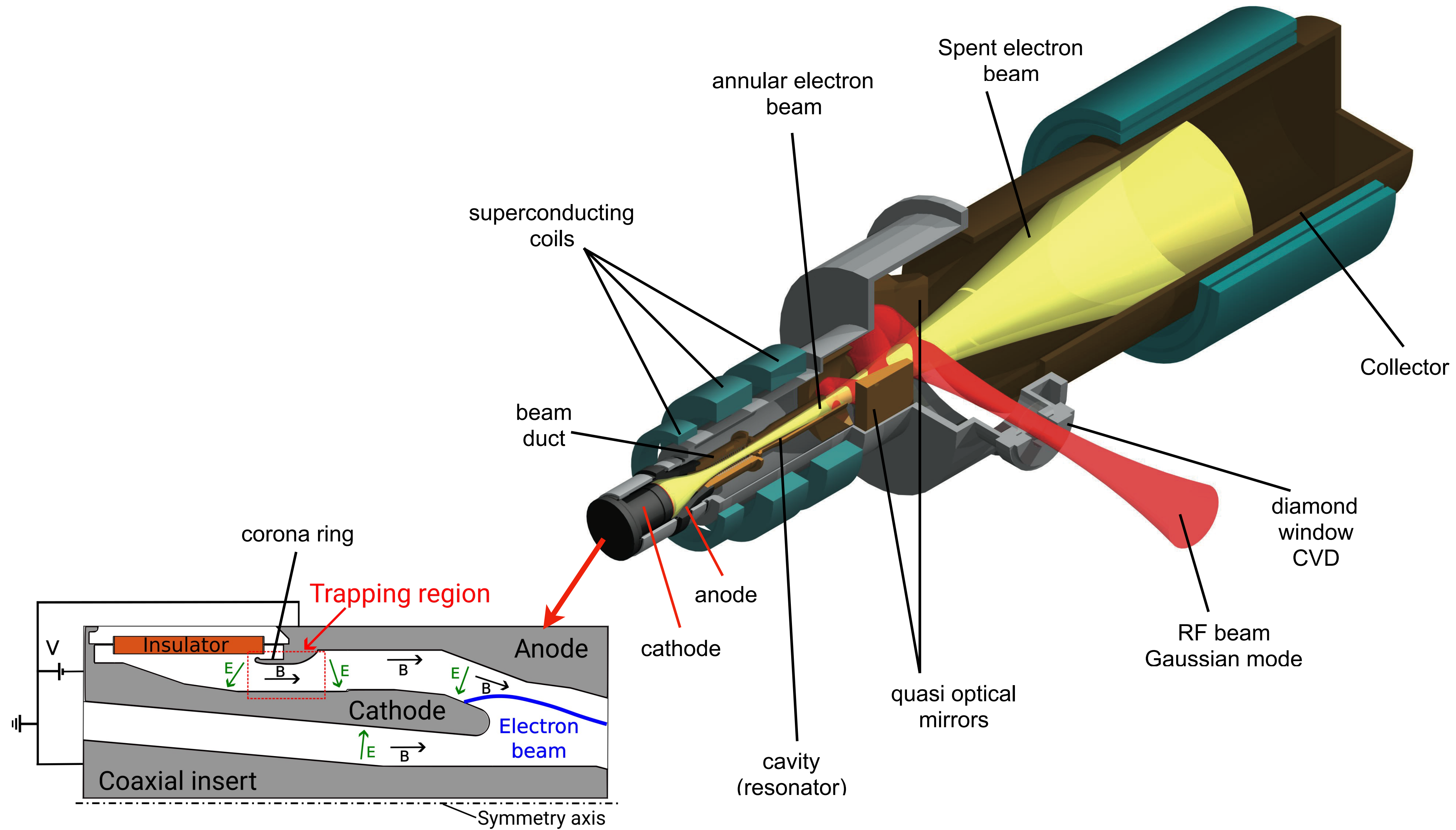
EPFL Introduction - The gyrotron as a high power mm wave source

- Micro-waves for ECRH
- 1 MW, 170 GHz continuous beam
- 24 1MW gyrotrons for ITER ECRH



Source: Courtesy of S. Alberti

EPFL Introduction - The gyrotron as a high power mm wave source

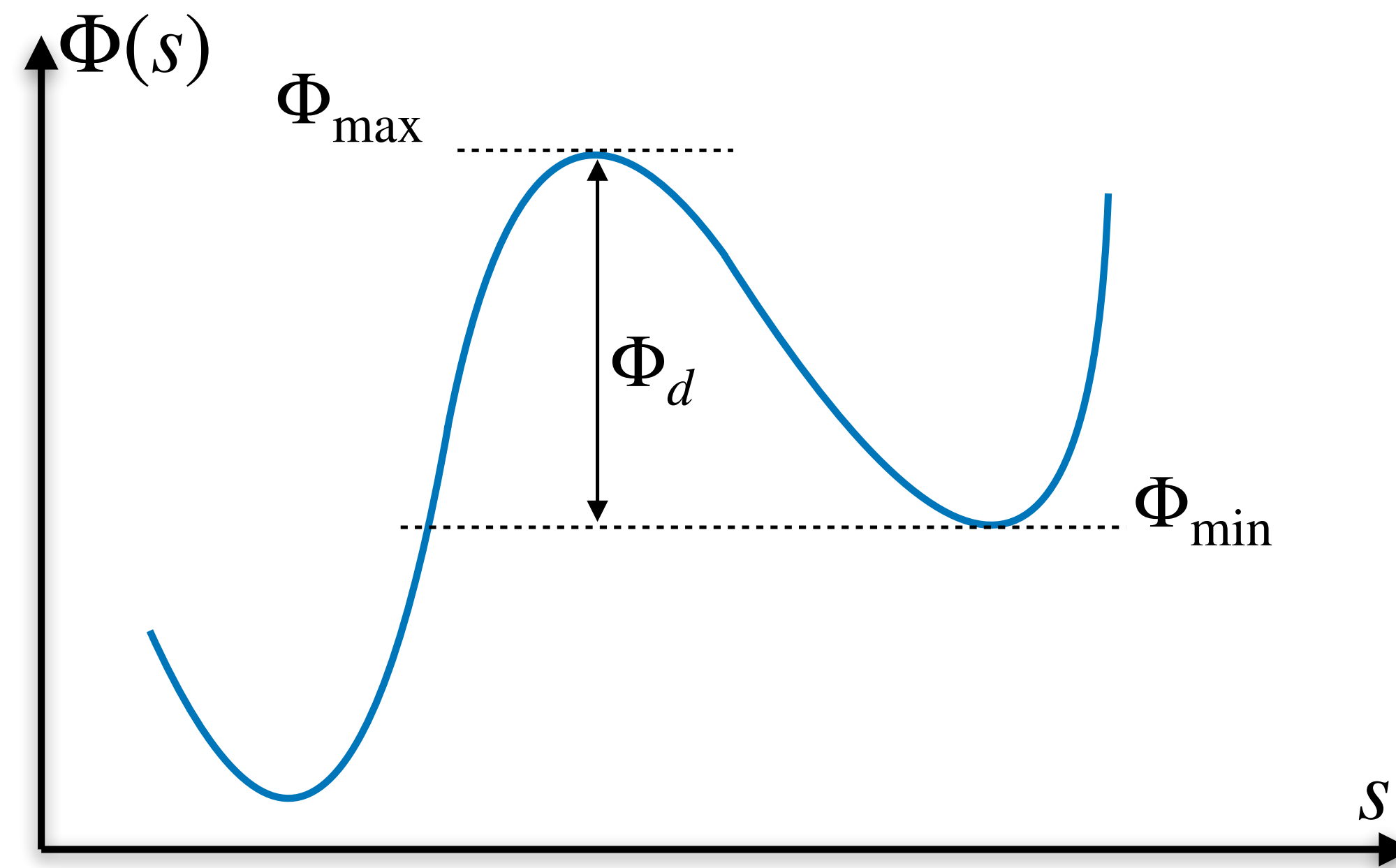
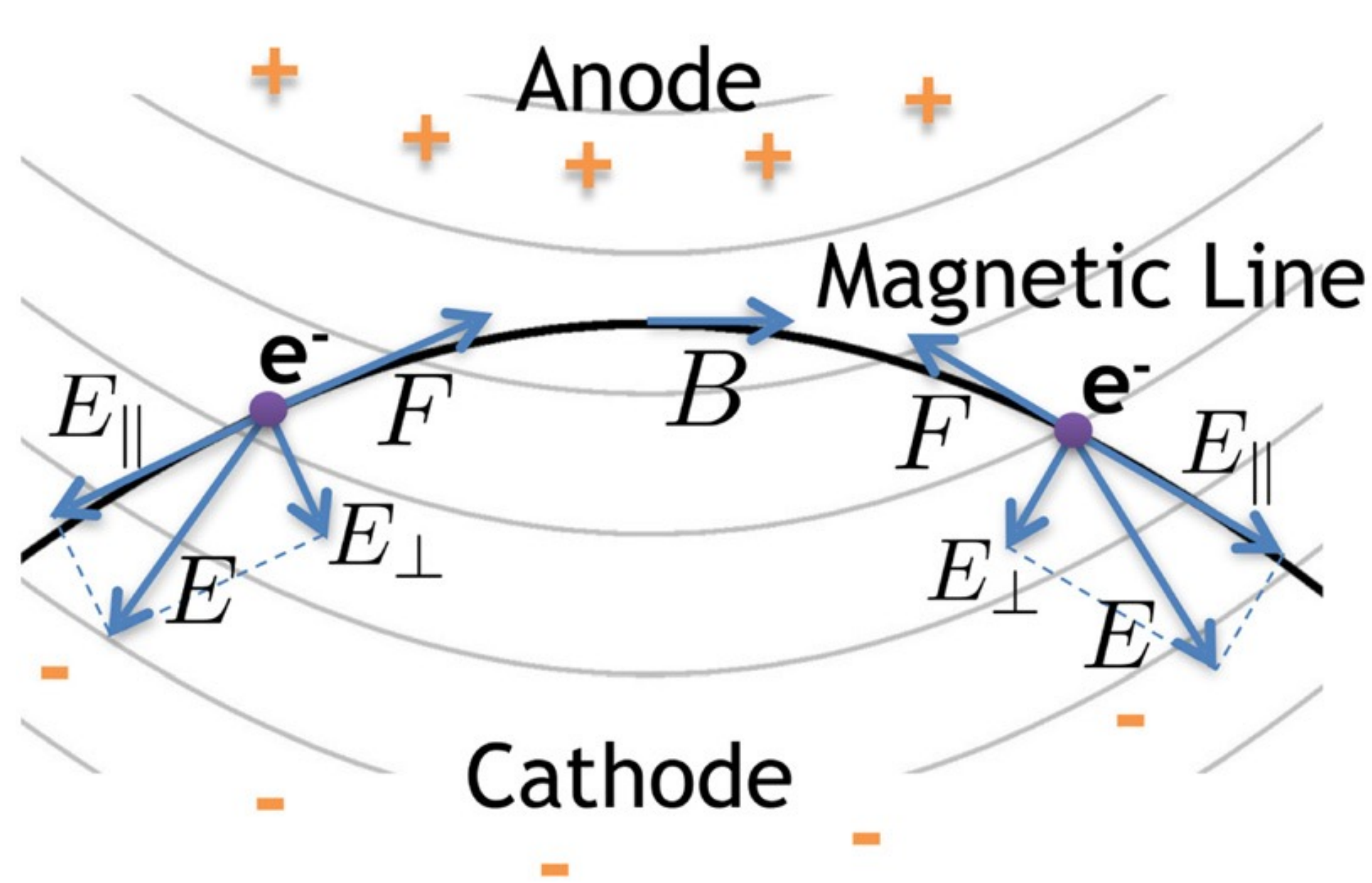


Region of interest

EPFL About the problem of trapping

- Due to **magnetic** and **electric** fields topology, some magnetic potential **wells** can form.
- Magnetic field line crosses twice an equipotential.
- Directional force keeps electrons **in the well** while they drift **azimuthally**.

$$F_{\parallel} = -e \cdot E_{\parallel}$$



Config leading to magnetic well [PPZ+16]

EPFL Theory: Choosing a model for IIEE

- We seek an expression for γ , the **electron yield per incident ion**.

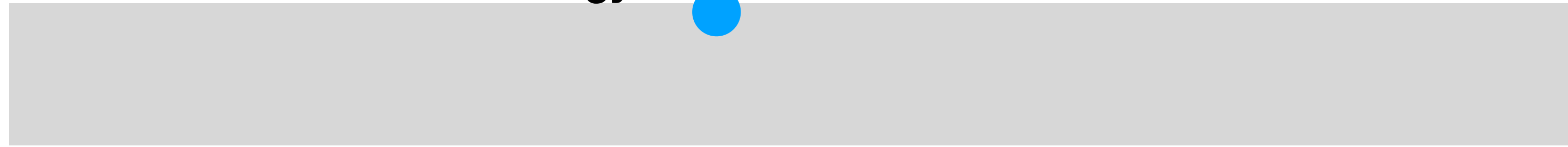
Incident ion
w/ energy E 



EPFL Theory: Choosing a model for IIEE

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Incident ion
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EPFL Theory: Choosing a model for IIEE

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k emitted e^- s.t
 $\langle k \rangle = \gamma(E)$



EPFL Theory: Choosing a model for IIEE

- We seek an expression for γ , the **electron yield per incident ion**.
- γ is expected to depend on the **incident particle energy**, some **material parameters** (target density, transport phenomena for produced electrons).
- Semi-empirical (kinetic) model: *Schou* - 1988 [DH]

$$\gamma = \Lambda \cdot \beta \cdot \left. \frac{dE}{dx} \right|_i,$$

where Λ contains the **cross-sections** dependence for energy deposition, β accounts for **energy transport** of the produced electrons, and $\left. \frac{dE}{dx} \right|_i$ corresponds to the **energy loss** of ions in the solid, per unit distance.

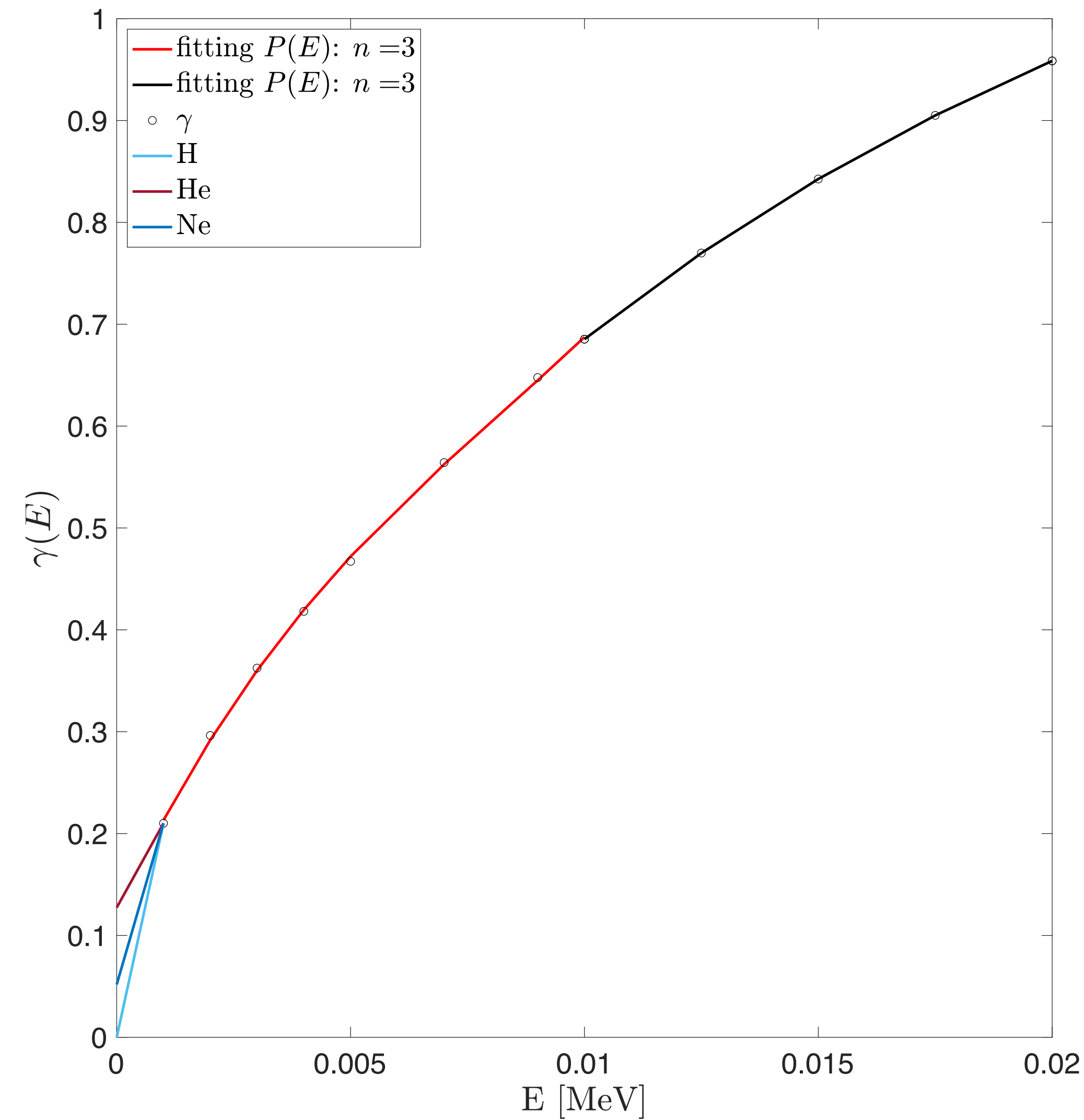
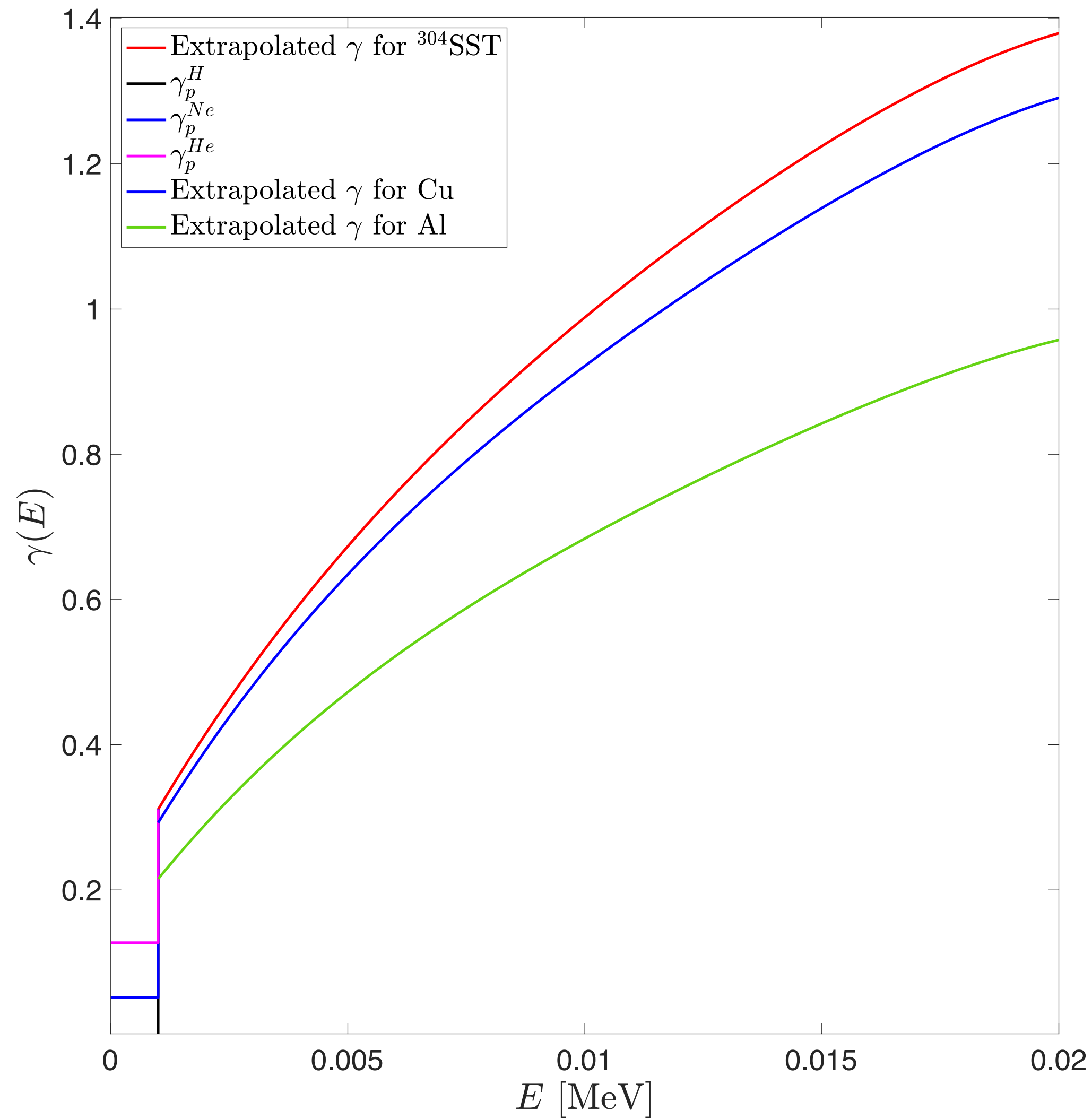
- For ions like H^+ , H_2^+ , the product $\Lambda \cdot \beta$ has been measured indep. of the metal and of approx. $10^{-3} \text{ cm/MeV} = 10^{-6} \text{ cm/keV}$.
- Hence our kinetic model reads $\gamma(E) = 10^{-6} \cdot \frac{dE}{dx} \Big|_i$, with $E \in [1,50] \text{ keV}$.
- Potential emissions: $E \in [0,1] \text{ keV}$, we need another model
- *Hagstrum* - 1954 [Kis73]:

$$\gamma \sim \frac{0.2}{\epsilon_F} \left(0.8 \cdot E_i - 2\phi \right),$$

where ϵ_F denotes the **Fermi** energy of the solid, E_i the energy to produce the **incident ion**, and ϕ the **work function** of the metal.

- Schou's model: **kinetic**, holds for $E \in [1,50]$ keV
- Hagstrum's model: **potential**, holds for $E \in [0,1]$ keV, constant γ
- **Transition between the two models** ? Linear interpolation between bottom of kinetic region and constant γ , so the yield is decreasing continuously on the whole range.

- Yield curve obtained by interpolating the points with cubic polynomials
- Right plot shows transition between Hagstrum's and Schou's model



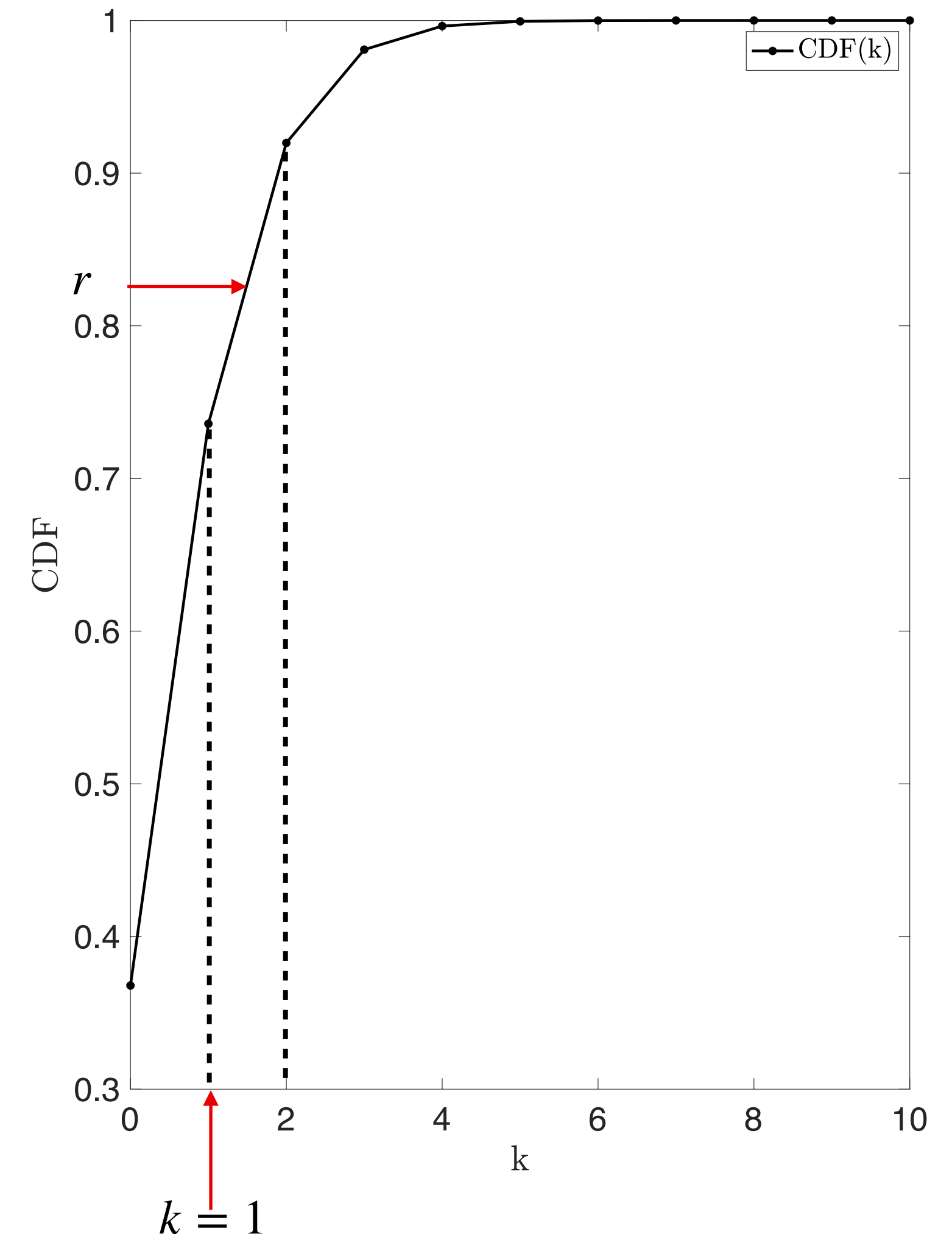
- Electron generation: discrete ‘rare’ events \implies **Poisson** distribution for the number of electrons generated per incident ion (parameter λ)

- Poisson s.t. $\lambda(E) = \gamma(E)$

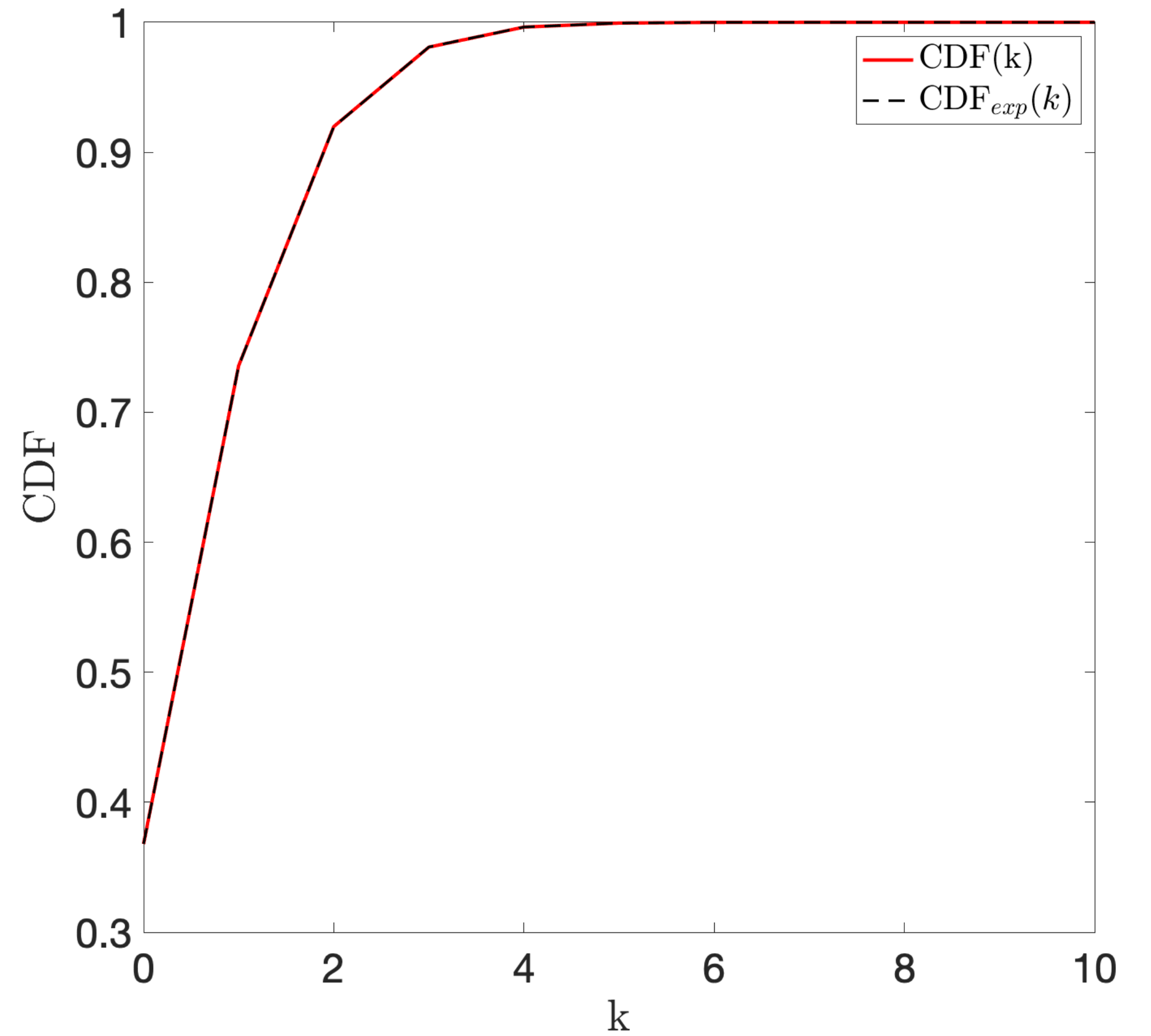
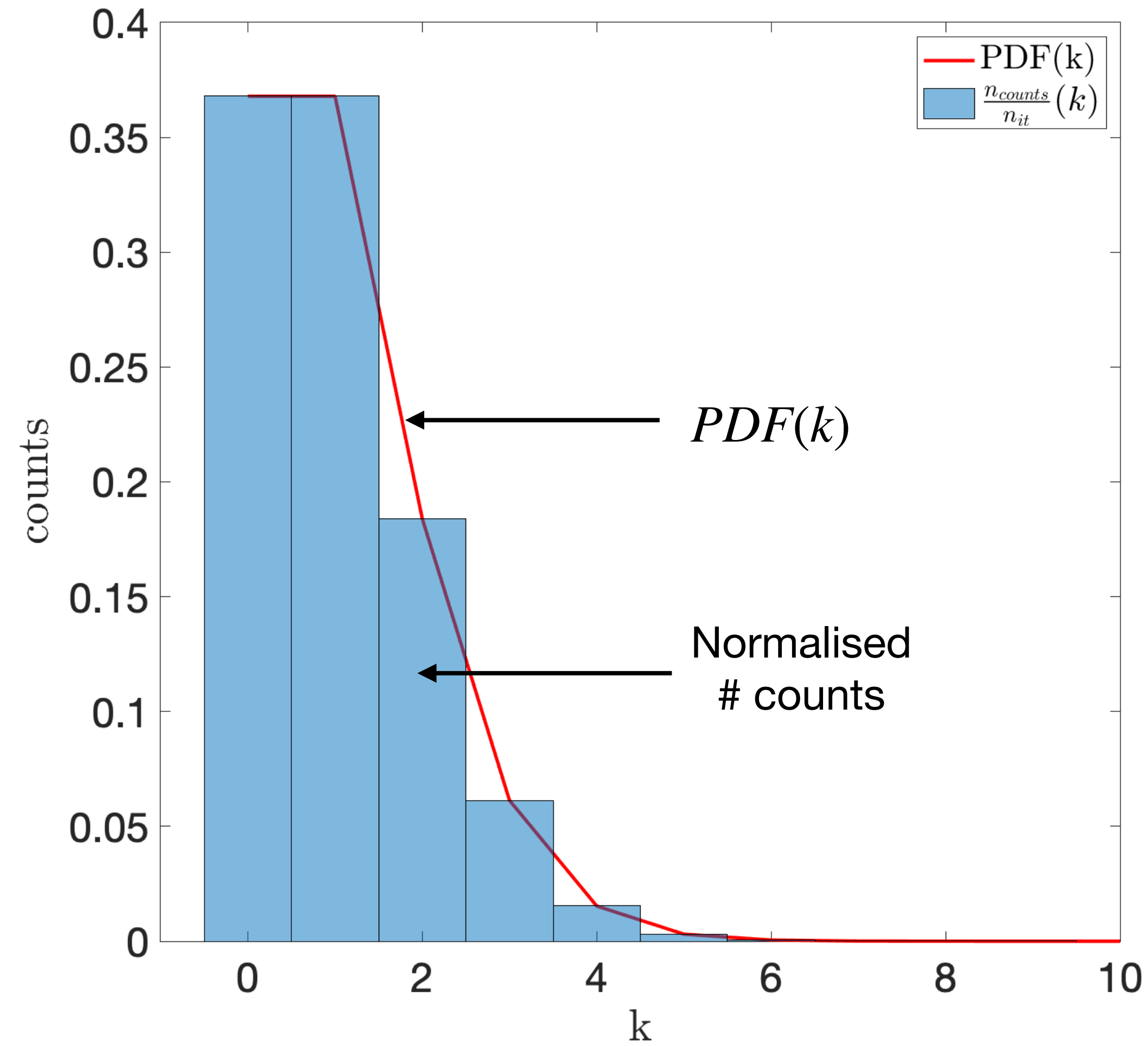
- $P(k) = \frac{e^{-\gamma(E)}}{k!}$, and CDF: $C(k) = \sum_{j=0}^{\lfloor k \rfloor} \frac{\gamma(E)^j}{j!}$

- Procedure:

- Generate a random number uniformly in $[0, 1[$
- Evaluate C with $\lambda = \gamma(E)$
- If $r \in [C(\tilde{k}), C(\tilde{k} + 1)[$ then $k = \tilde{k}$.

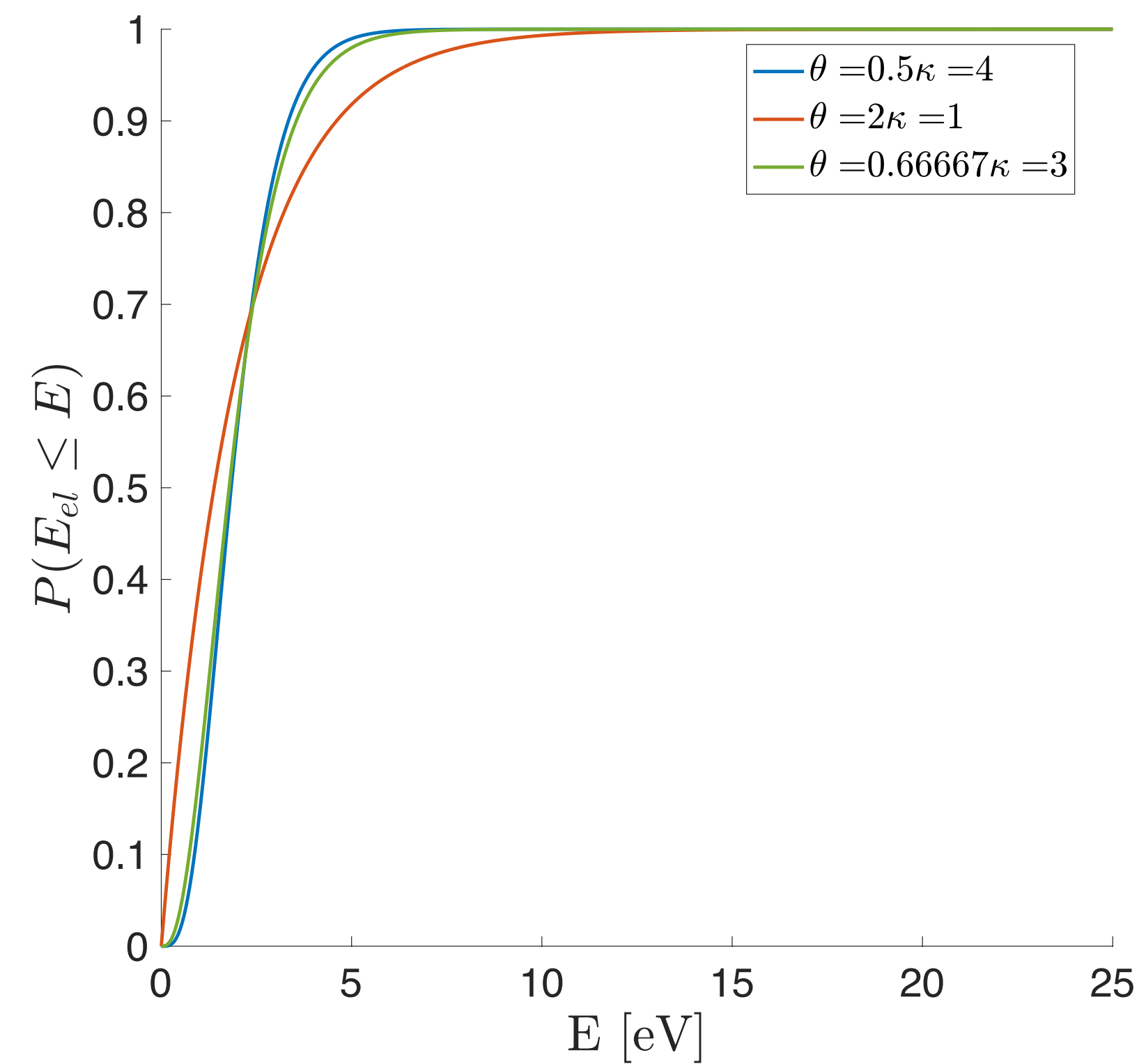
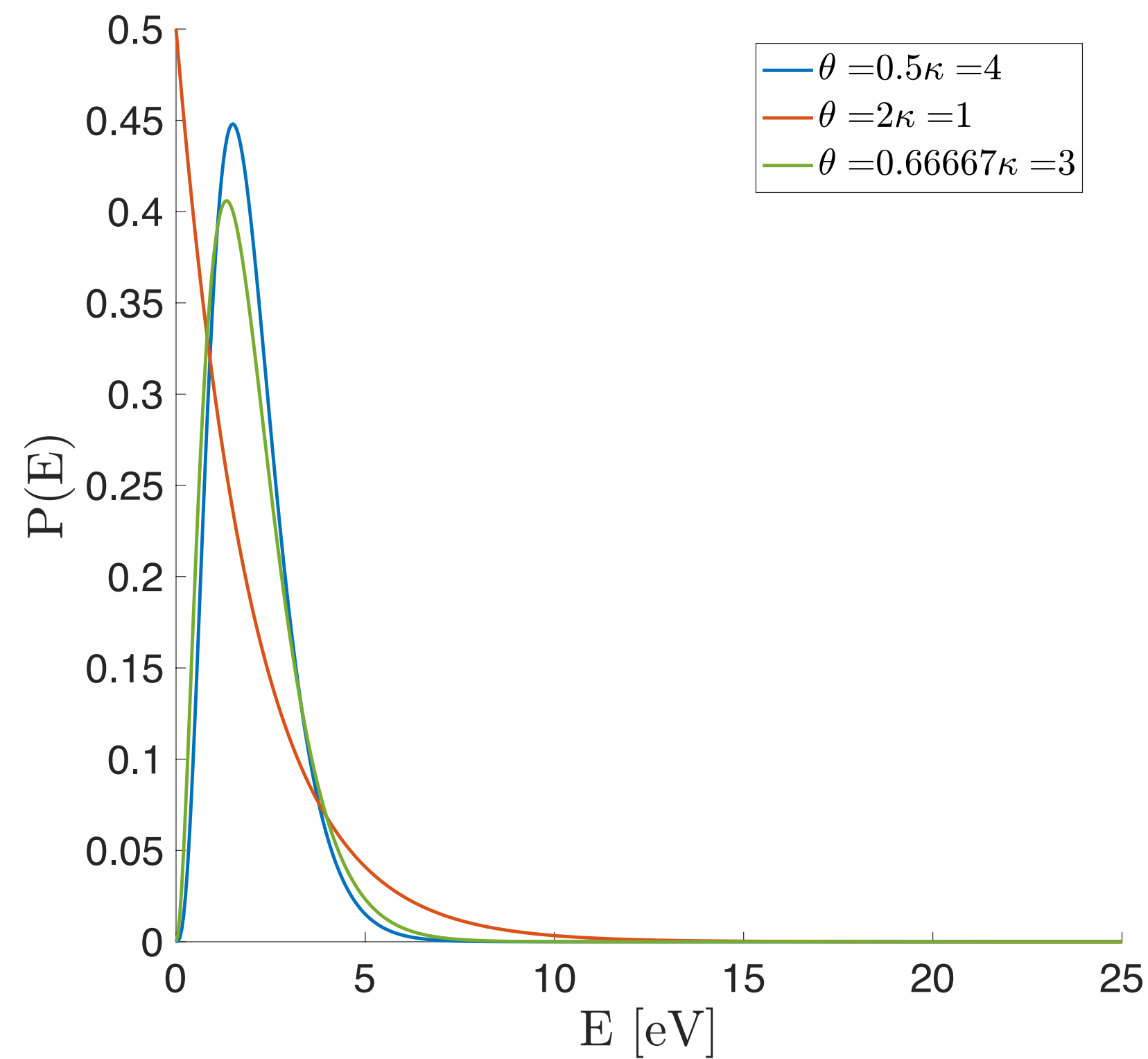


EPFL Electron generation - Test of Poisson generator



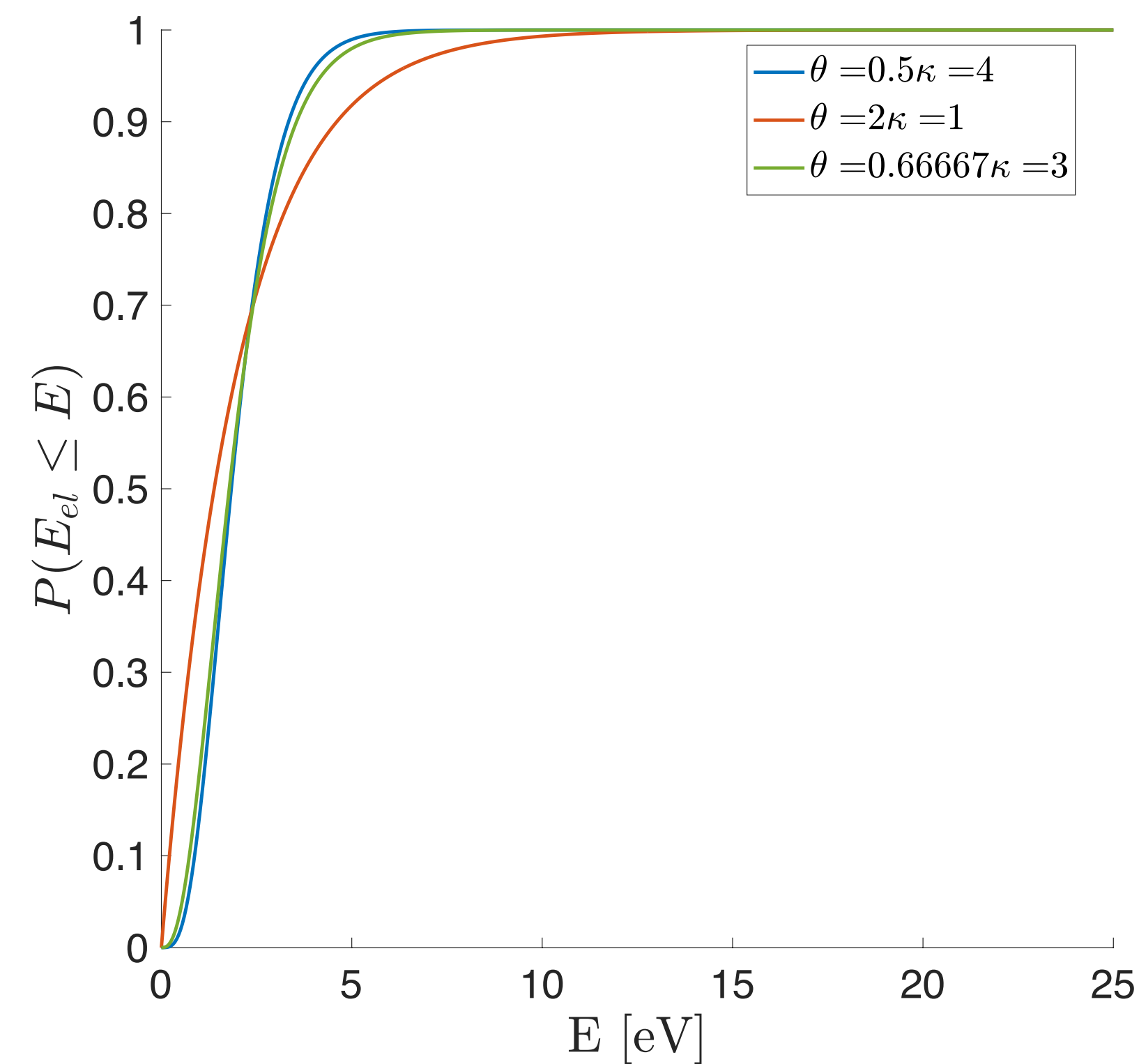
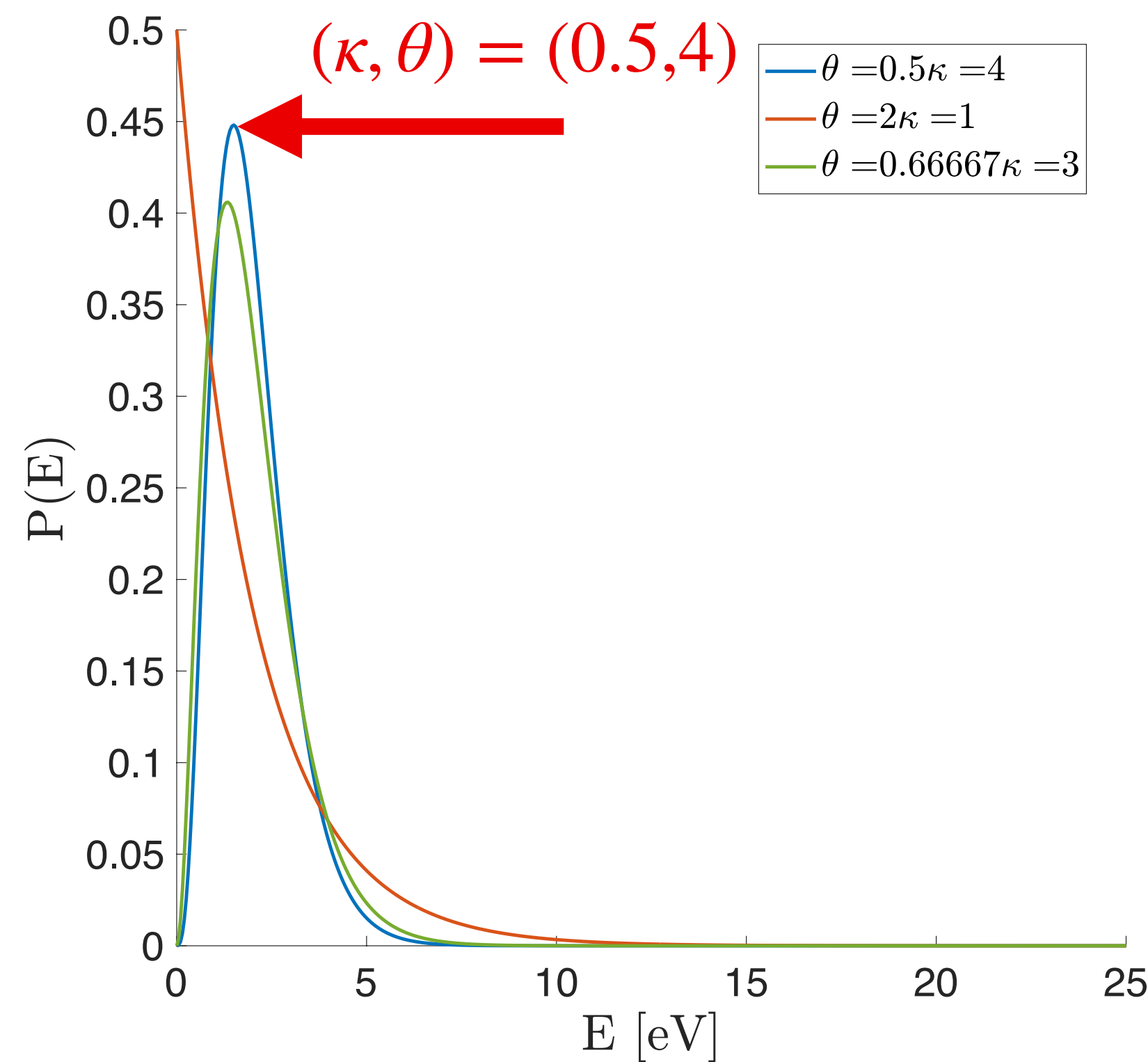
EPFL Implementation: Energy distribution of emitted electrons

- According to [DH] and [PPZ+16]: follows a gamma distribution that averages at 2 eV.
- Recall the two parameters: **shape** param. κ and **scale** param. θ s.t average $m = \kappa \cdot \theta$



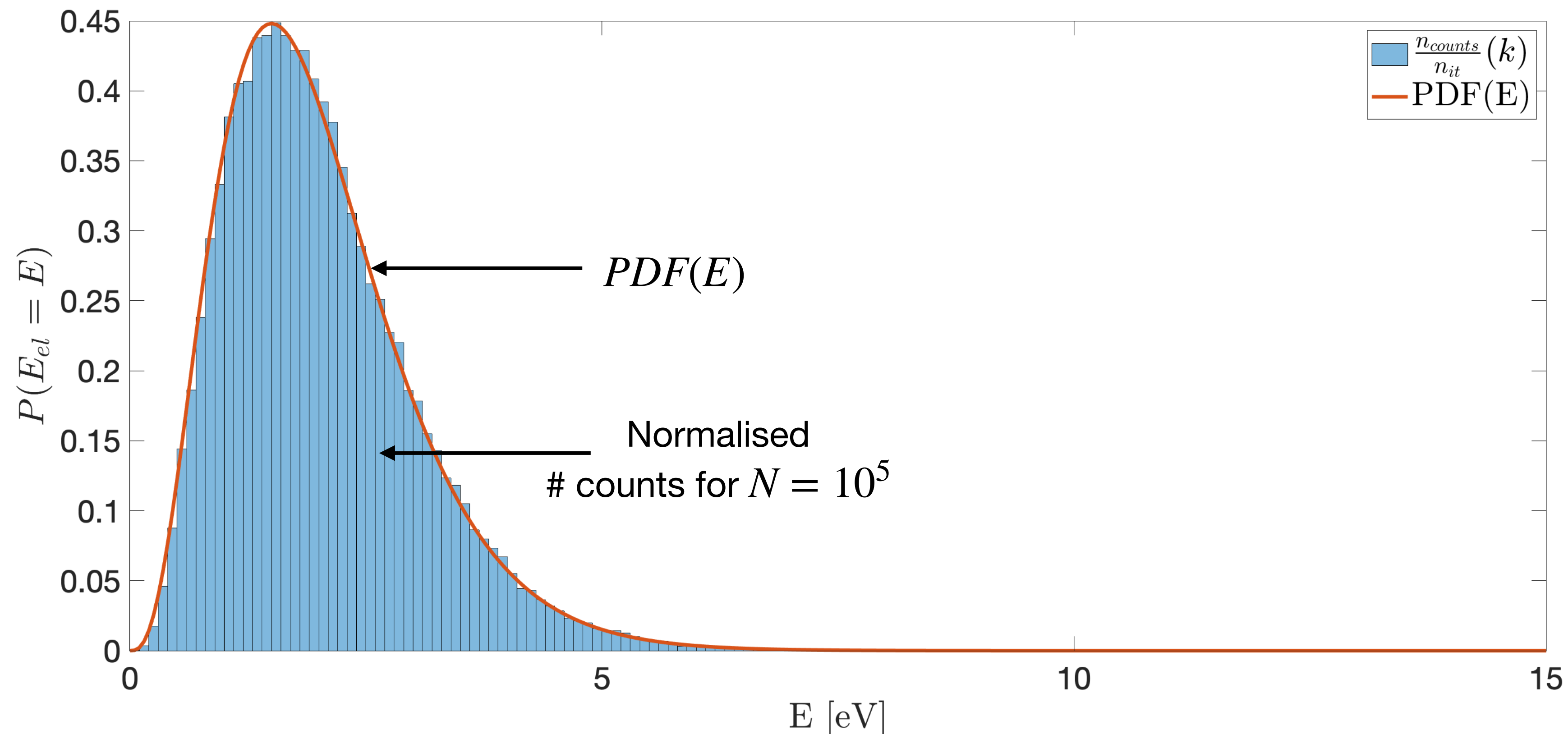
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- Chose $(\kappa, \theta) = (0.5, 4)$ so that peak prob closer to 2

- Procedure: generate a random number r uniformly in $[0,1[$
- Evaluate the CDF in the range $[0,15]$ eV with $N = 500$ points
- Take E as $E := \min_{\tilde{E}} |r - C(\tilde{E})|$



EPFL Implementation - summary

- Identify each ion disappearing, evaluating the geometric weight (see [LB22])

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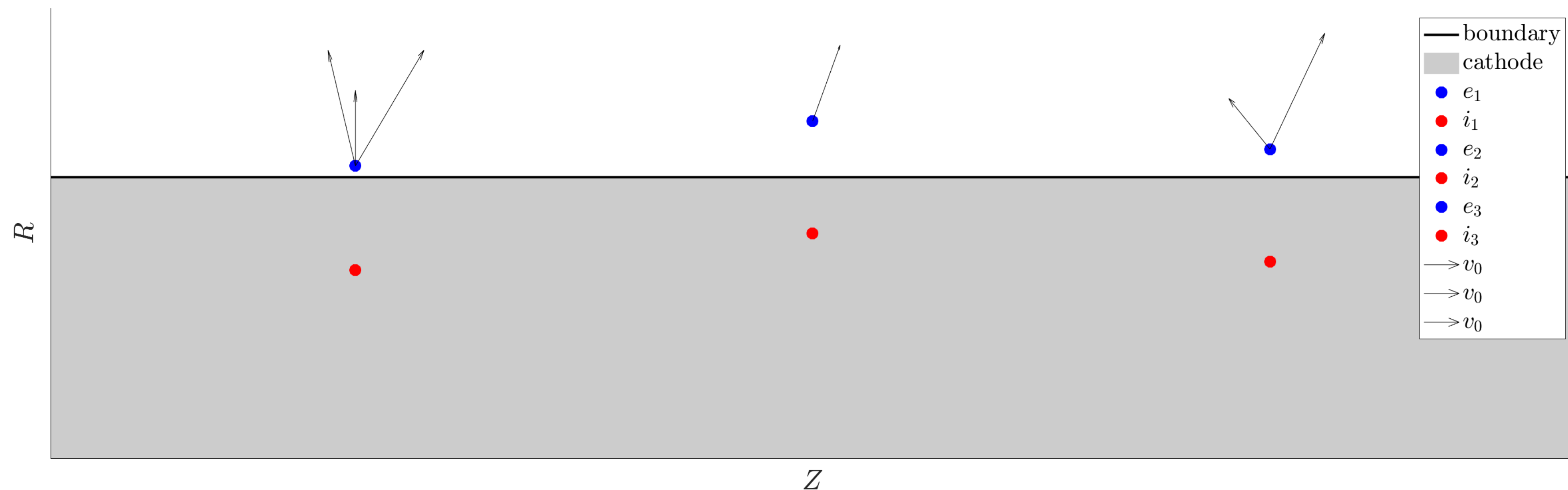
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- e^- placed at the last position **inside** the domain + given an energy randomly gamma distr.

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- Ion safely removed from the simulation

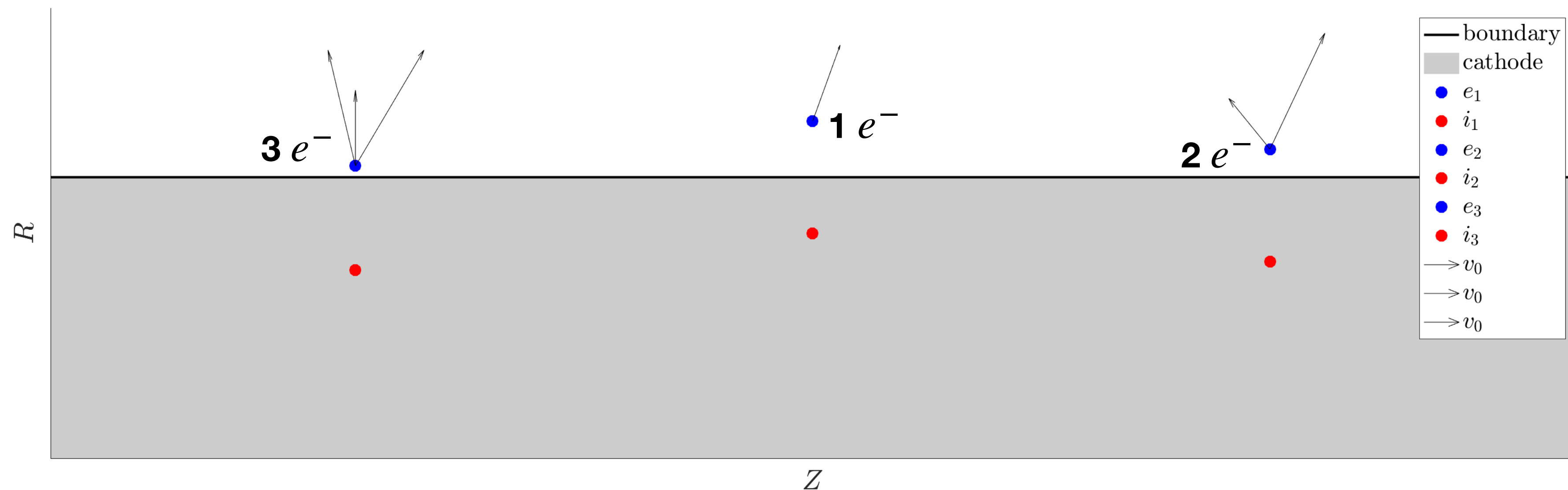
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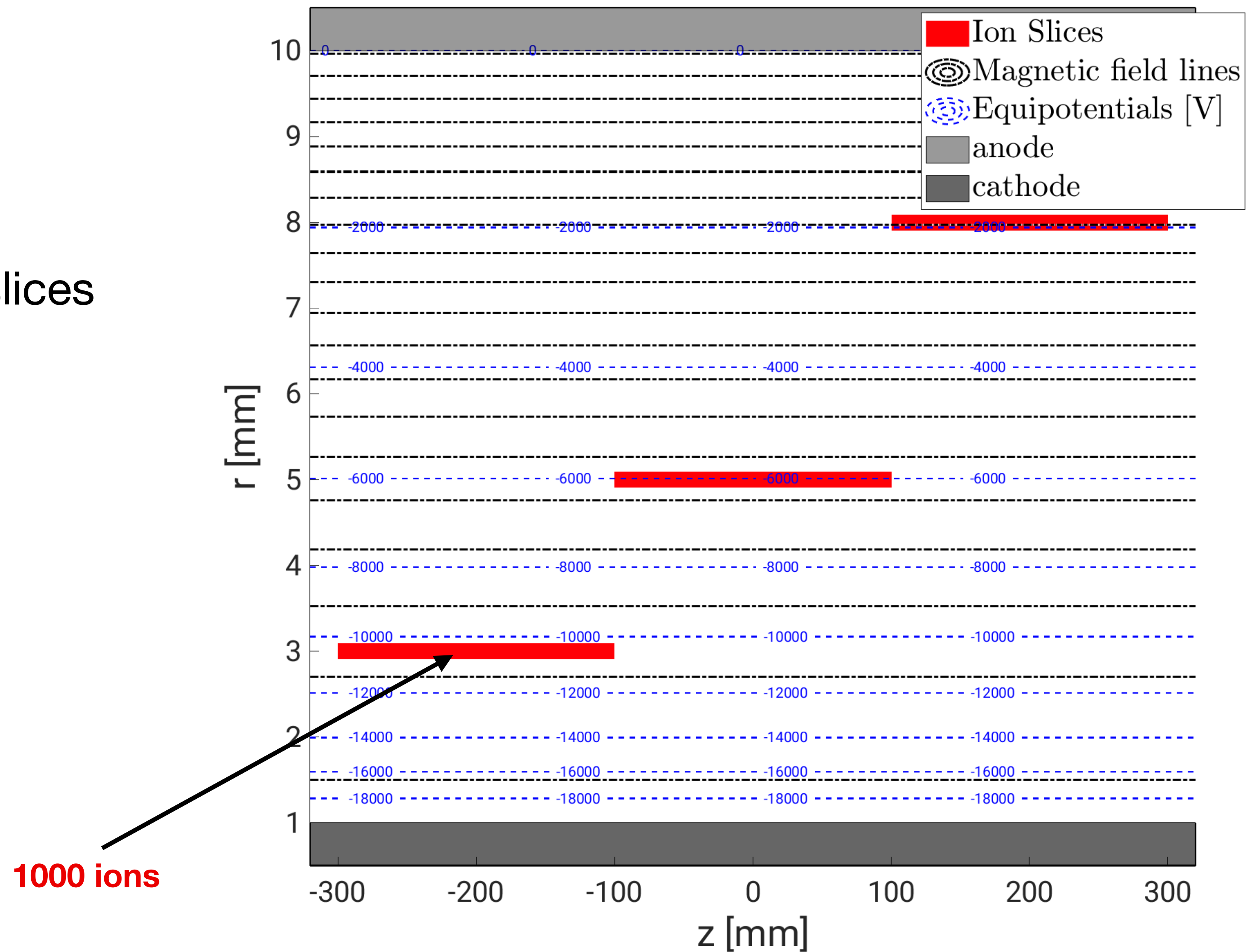


EPFL Implementation - summary

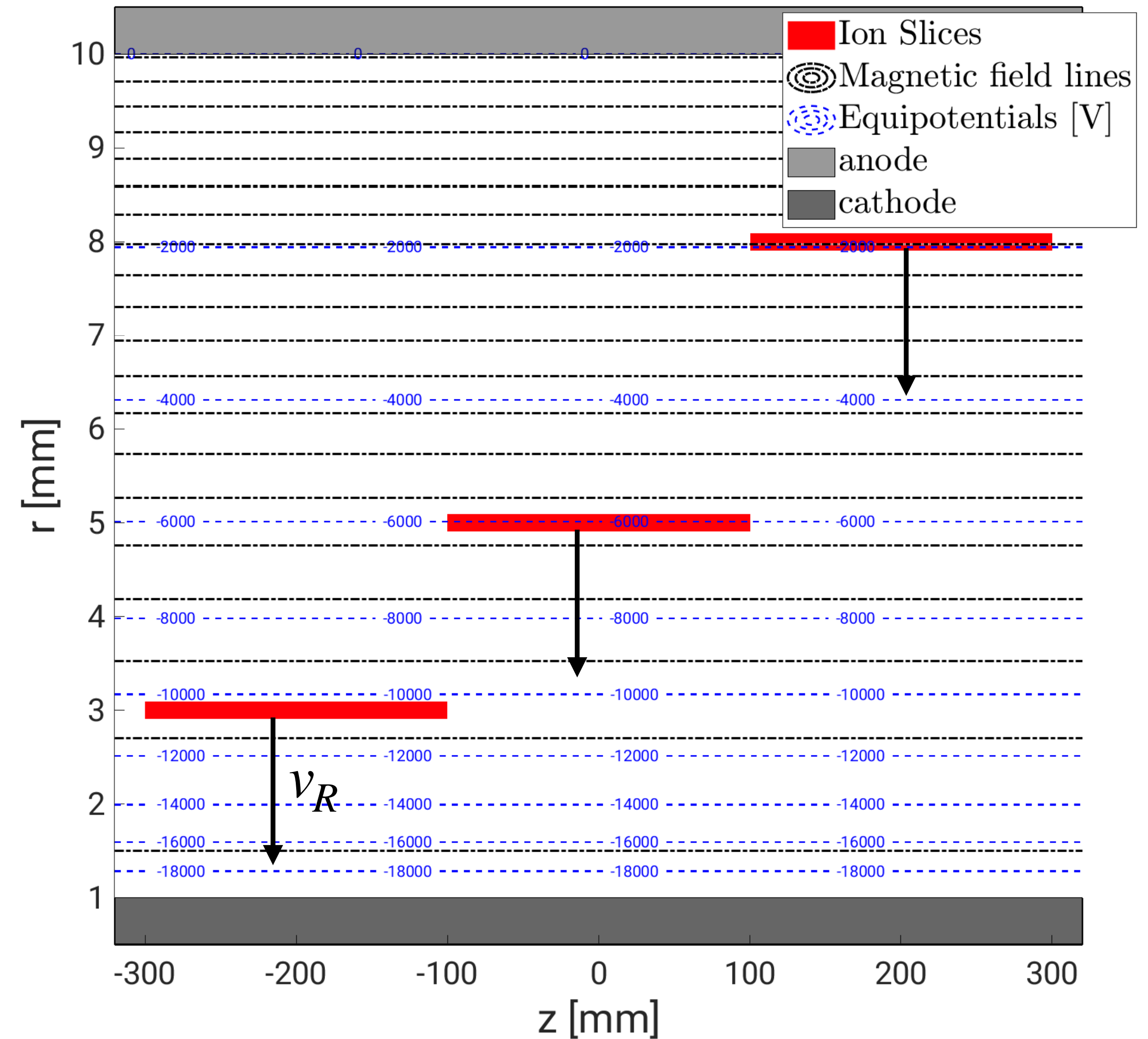
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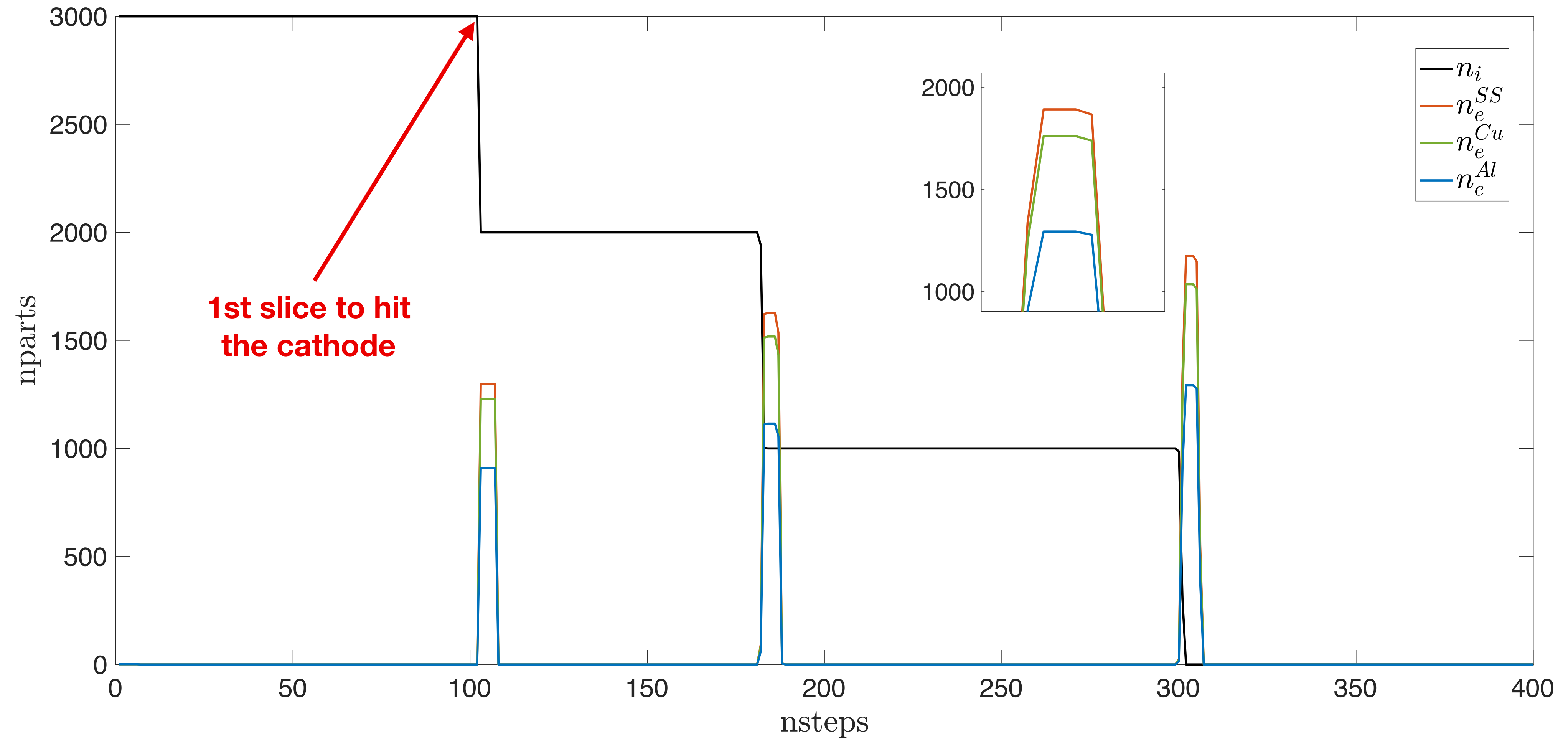


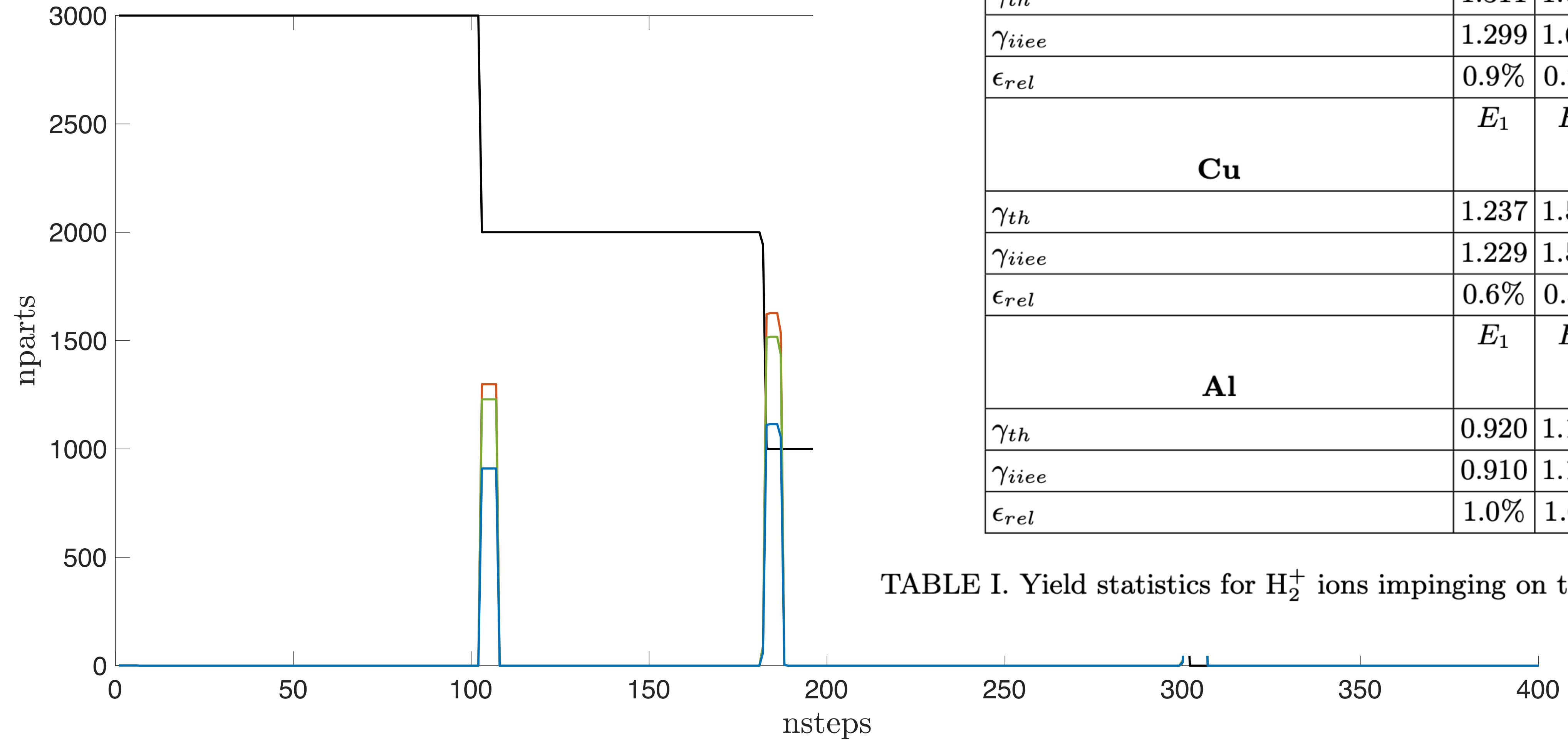
- Initial configuration: 3 horizontal slices of H_2^+ ions - SS, Al and Cu.
- $\Delta\Phi = 20$ kV. $B = 0.21$ T.
- $r_a = 10^{-3}$ m , $r_b = 10^{-2}$ m



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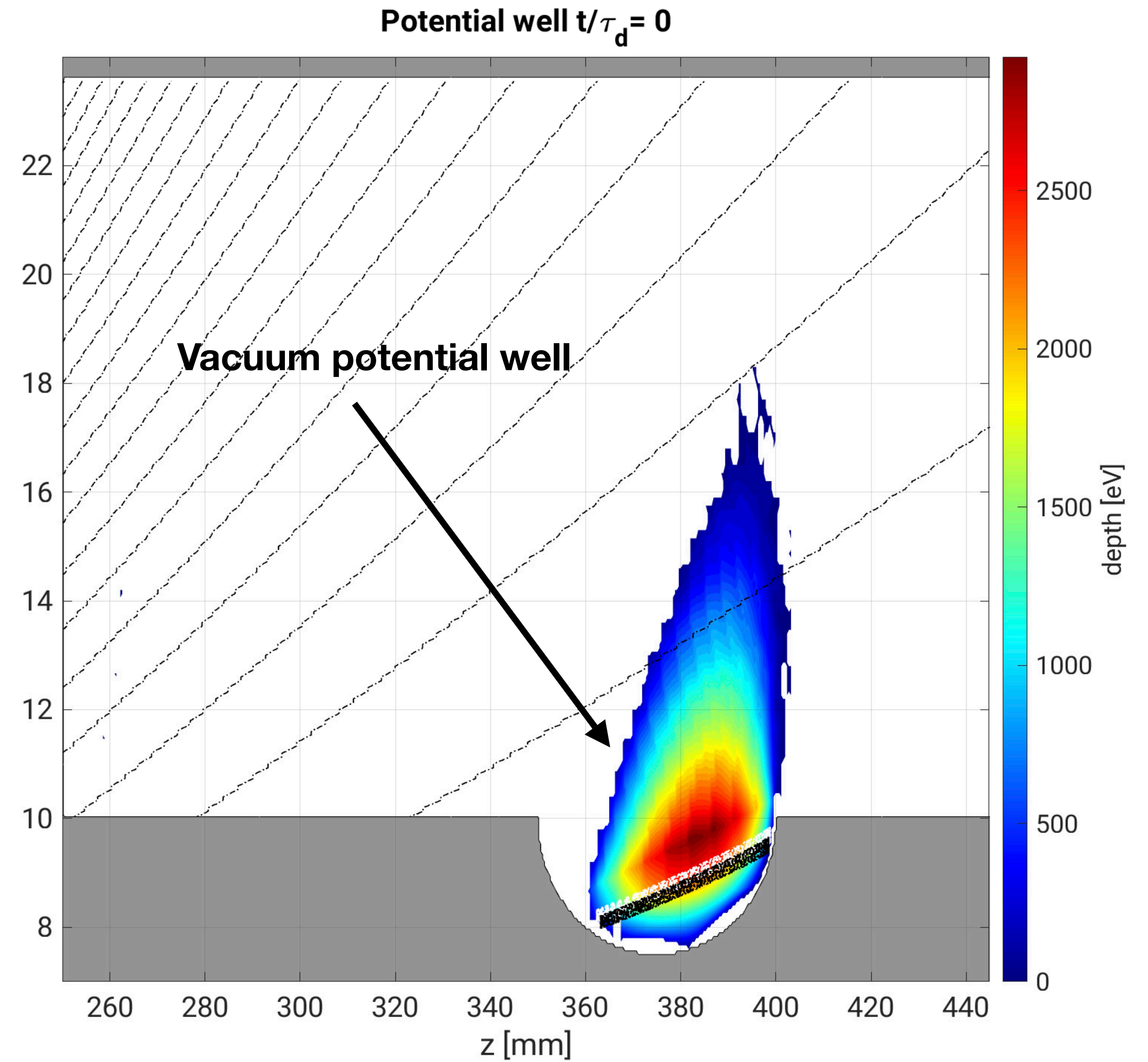
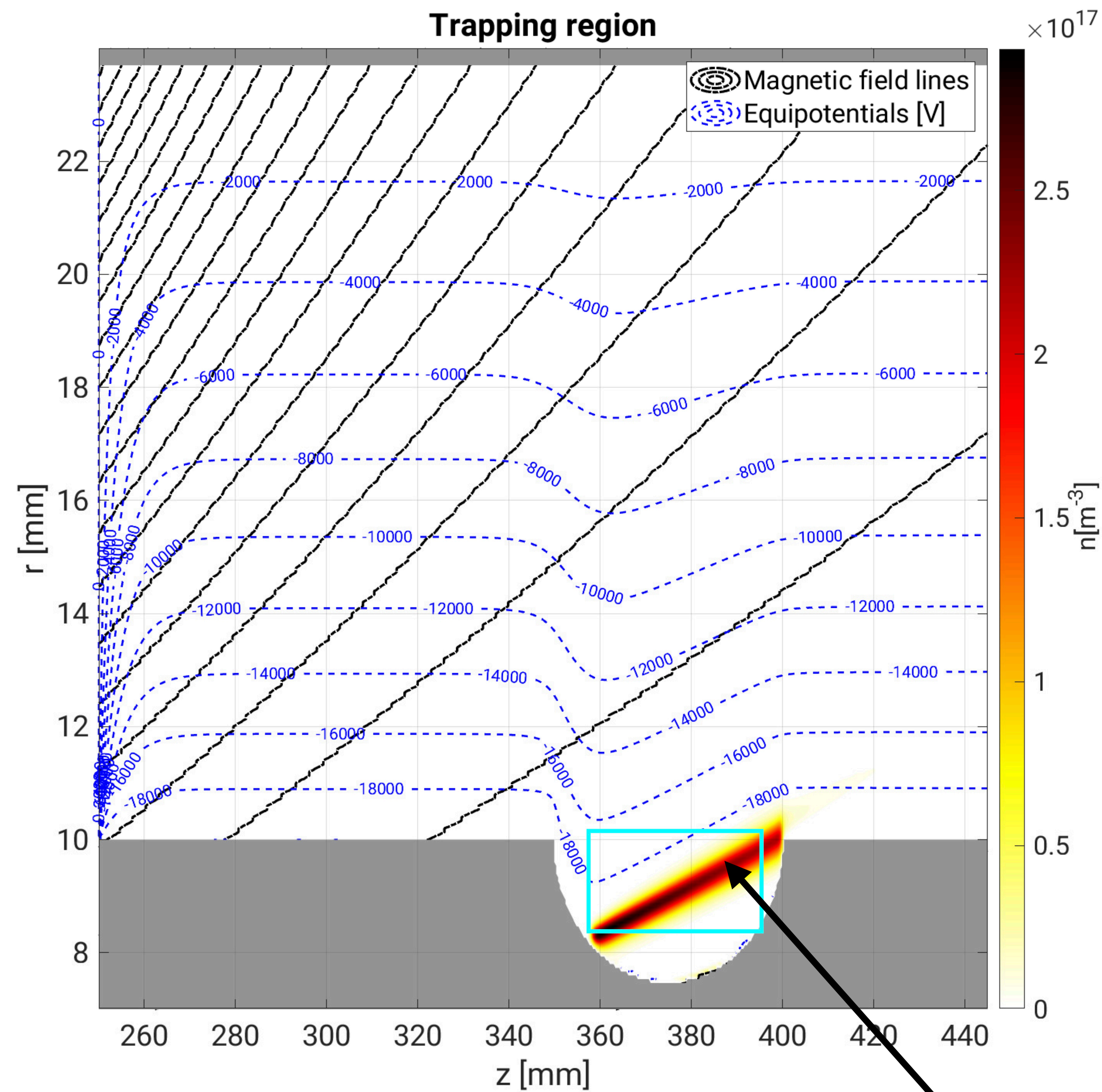






	E_1	E_2	E_3
^{304}SS			
γ_{th}	1.311	1.623	1.870
γ_{iiee}	1.299	1.627	1.891
ϵ_{rel}	0.9%	0.2%	1.1%
	E_1	E_2	E_3
Cu			
γ_{th}	1.237	1.522	1.746
γ_{iiee}	1.229	1.518	1.760
ϵ_{rel}	0.6%	0.3%	0.8%
	E_1	E_2	E_3
Al			
γ_{th}	0.920	1.133	1.297
γ_{iiee}	0.910	1.115	1.293
ϵ_{rel}	1.0%	1.6%	0.3%

TABLE I. Yield statistics for H_2^+ ions impinging on the three materials

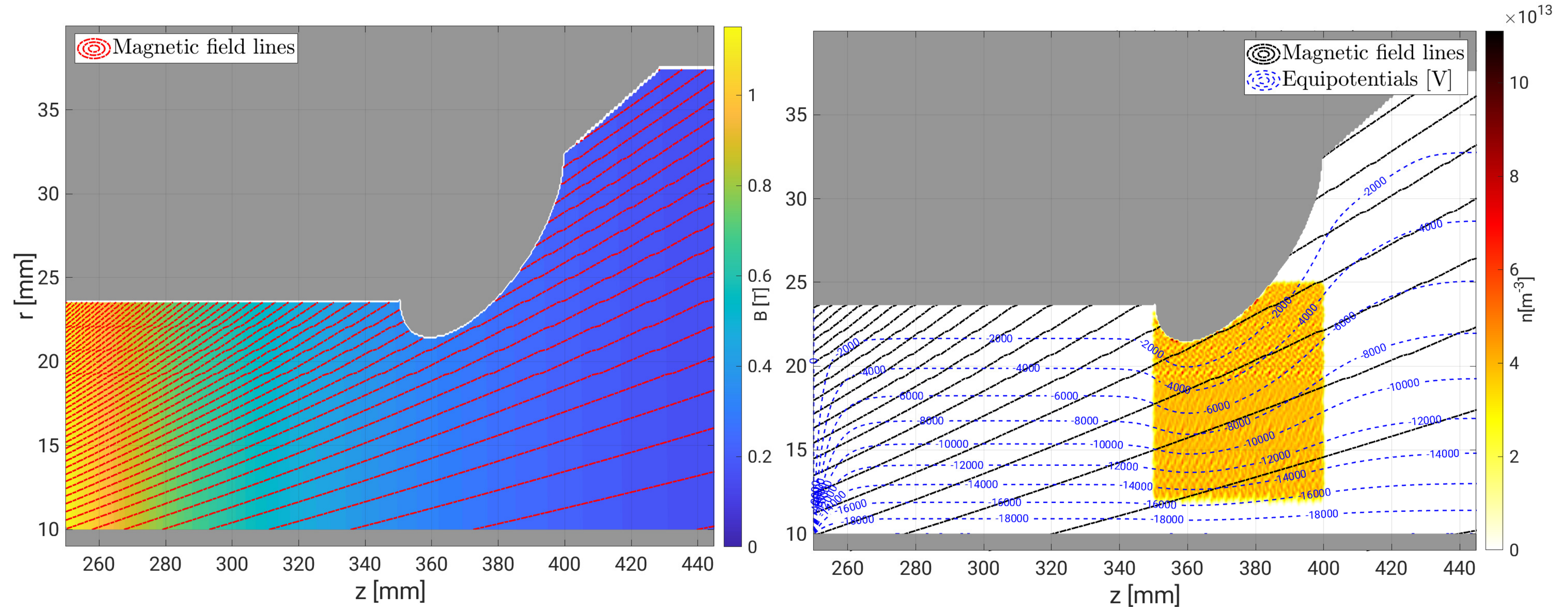


Cloud to emphasize trapping region

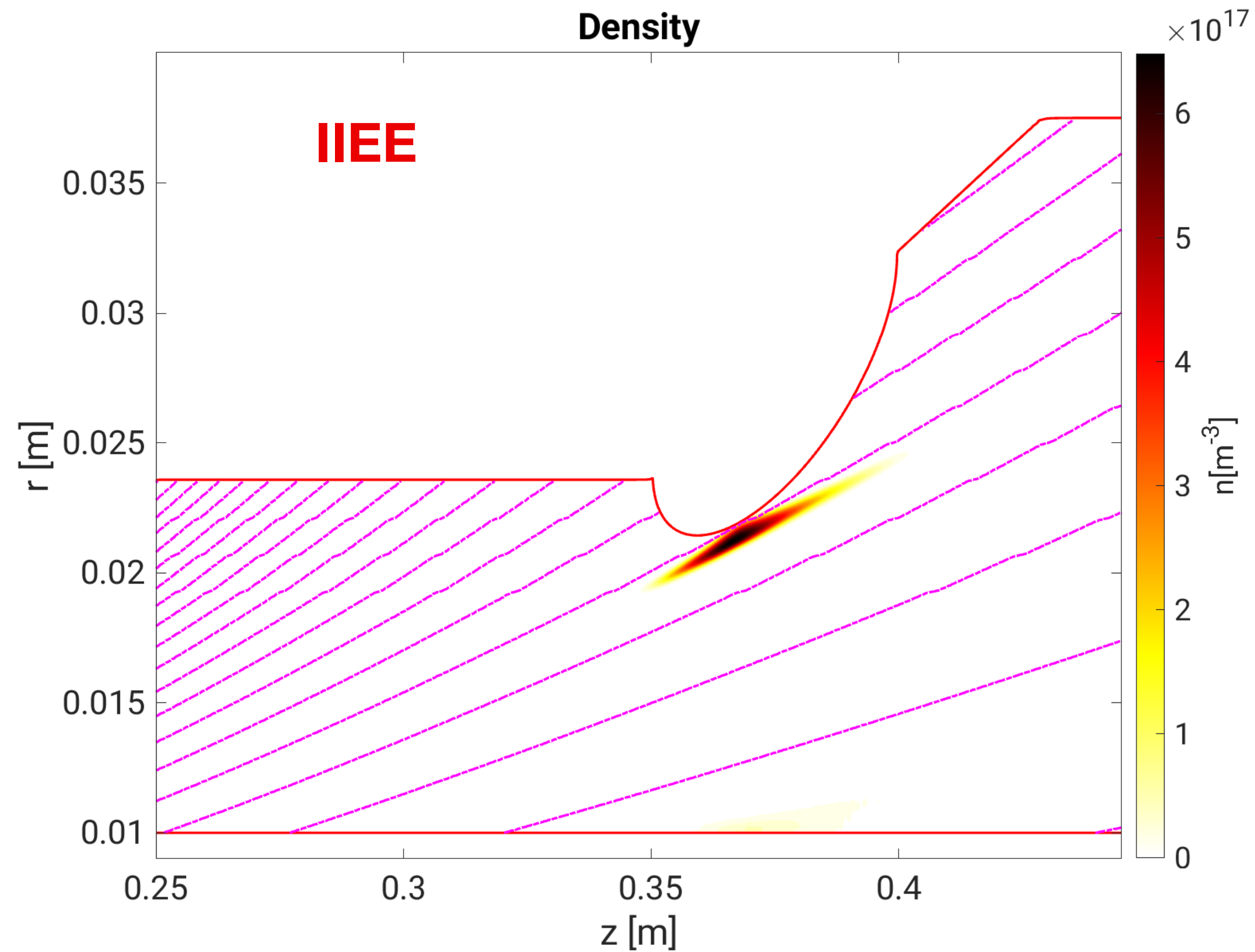
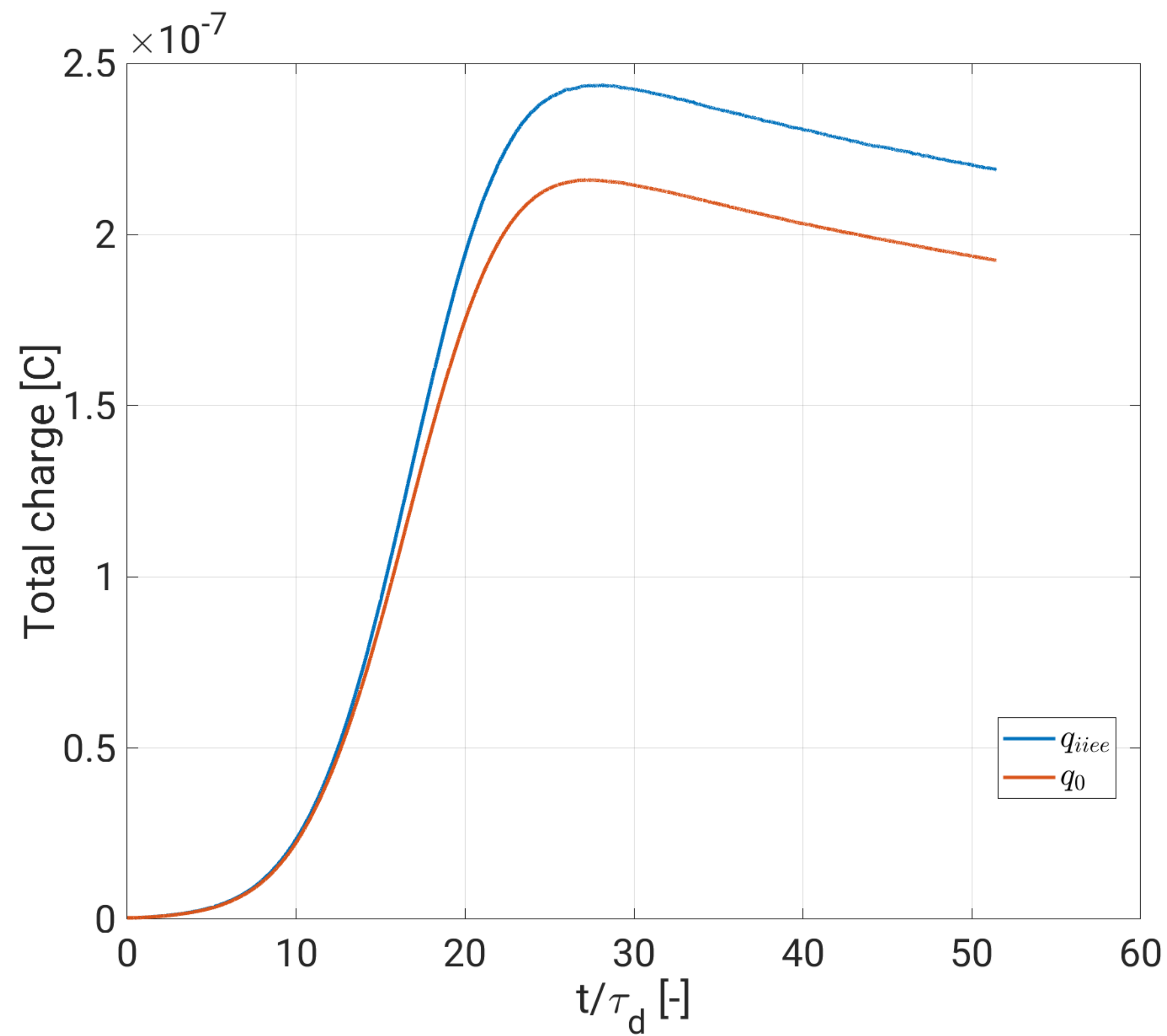
EPFL Cloud formation and dynamics: The case TREX (slanted)

- Physical/numerical parameters

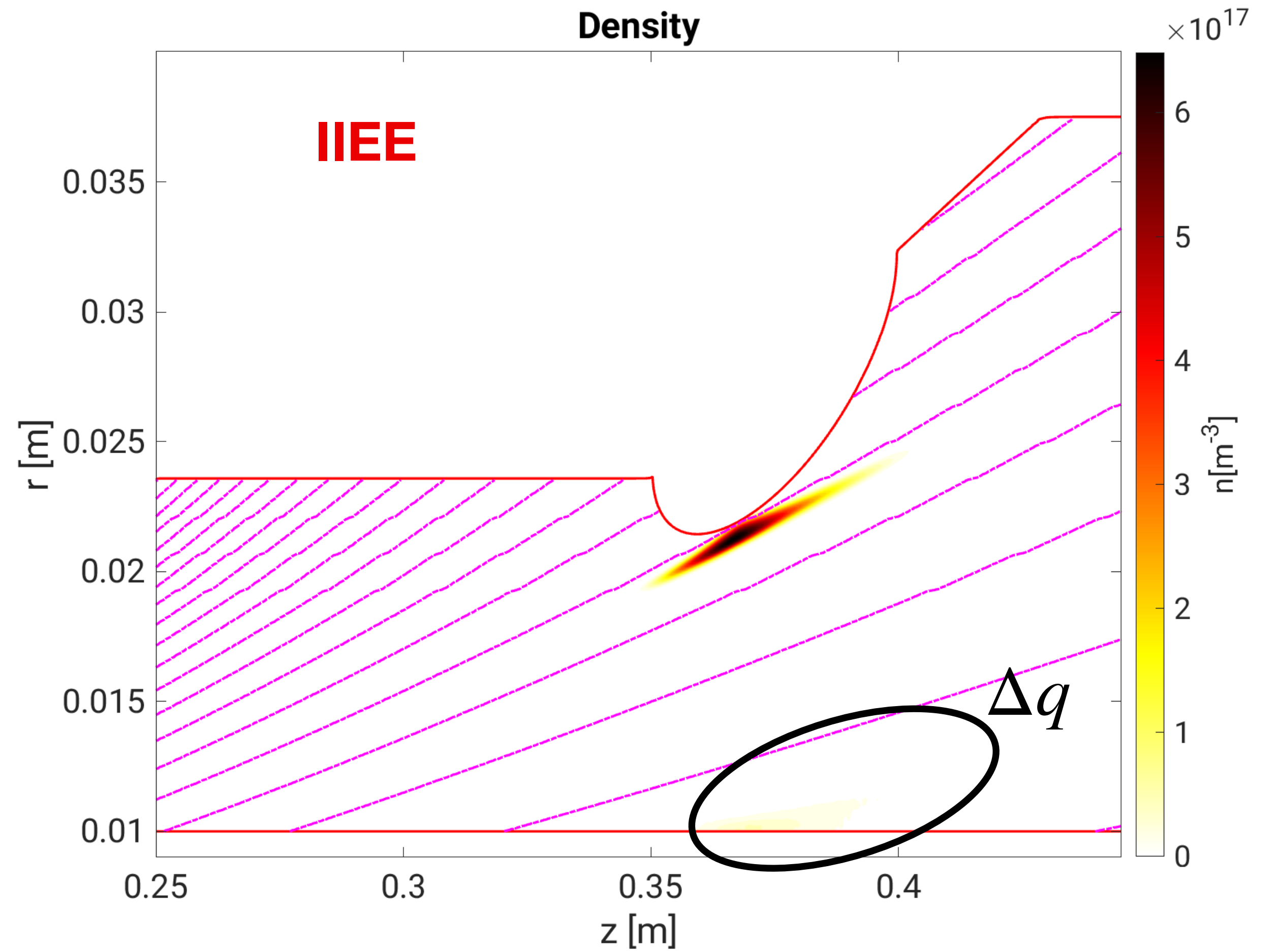
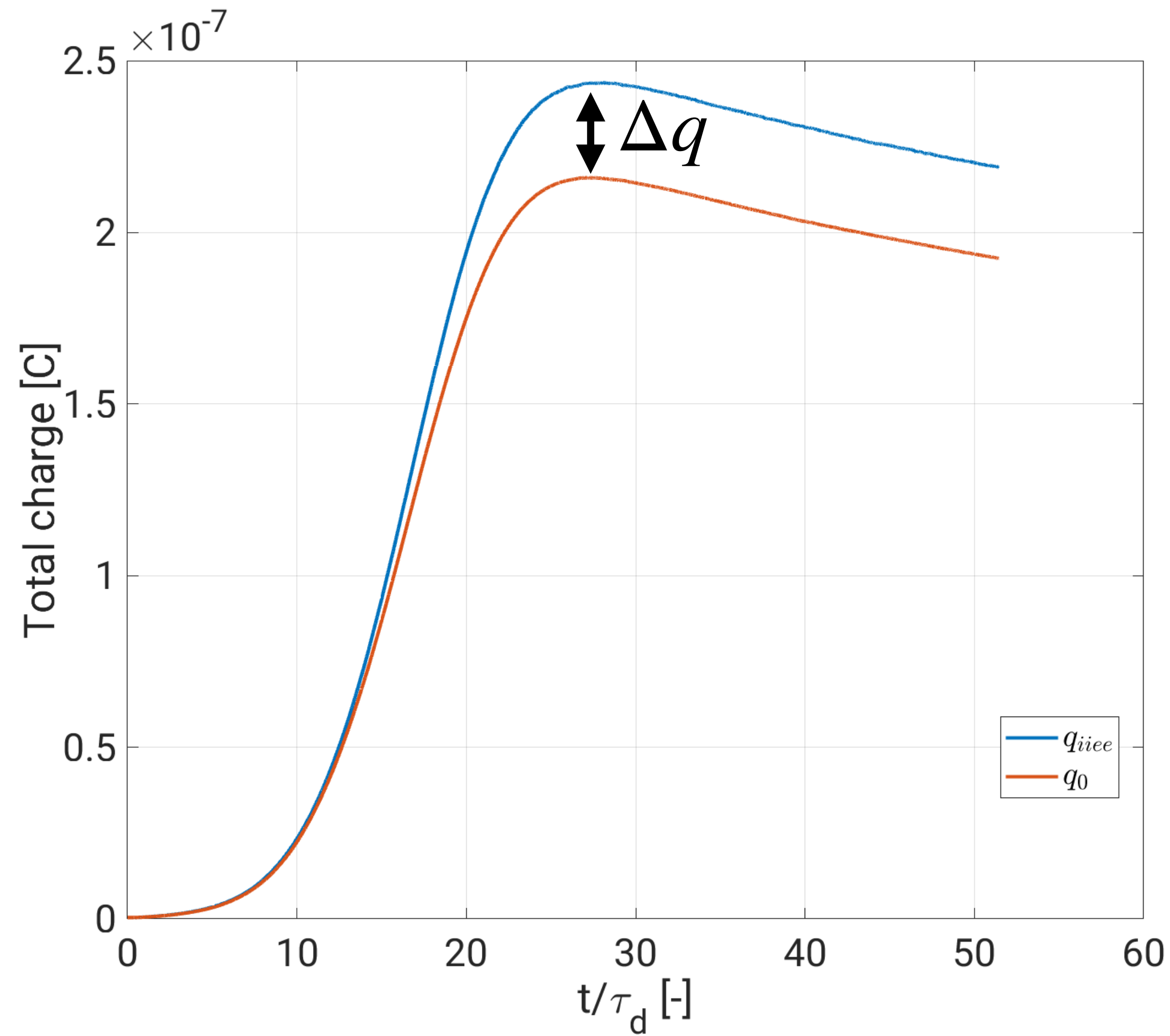
- $\Delta\Phi = 20$ kV
- Neutral pressure $P_n \sim 2 \cdot 10^{-2}$ mbar



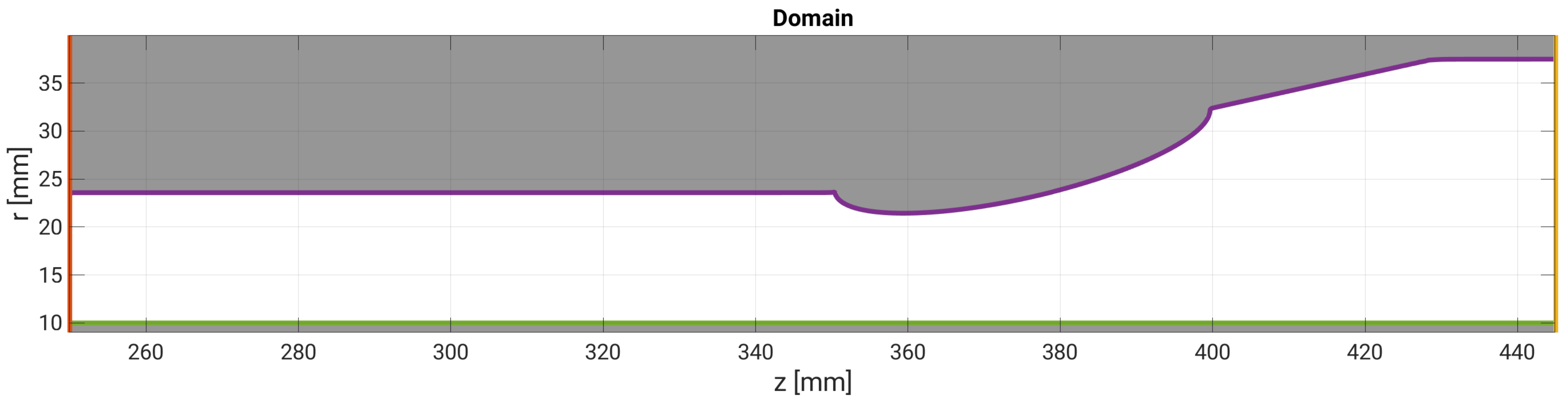
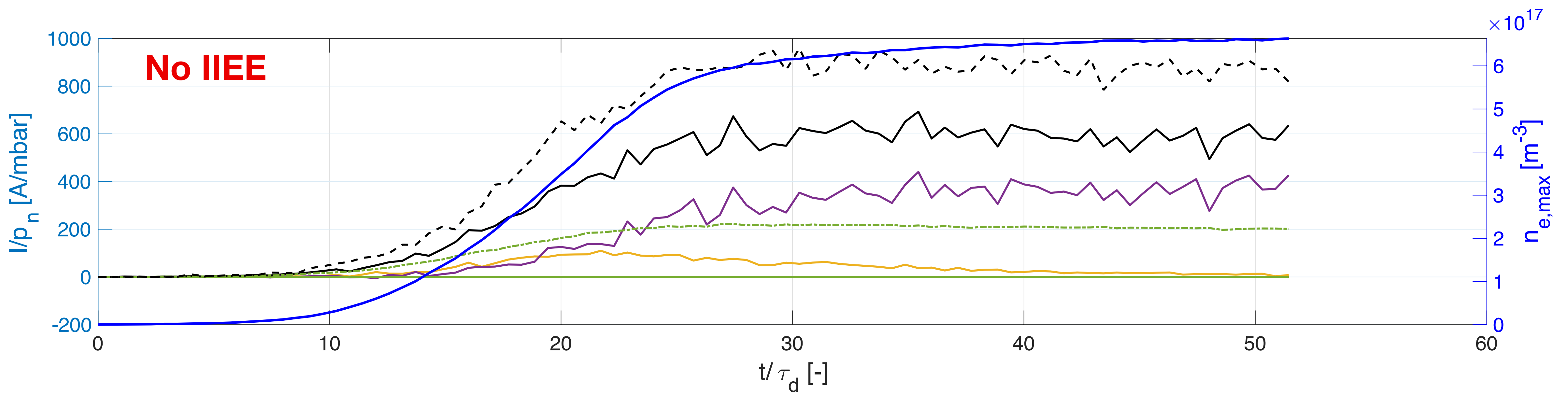
EPFL Cloud formation and dynamics: TREX slanted geometry



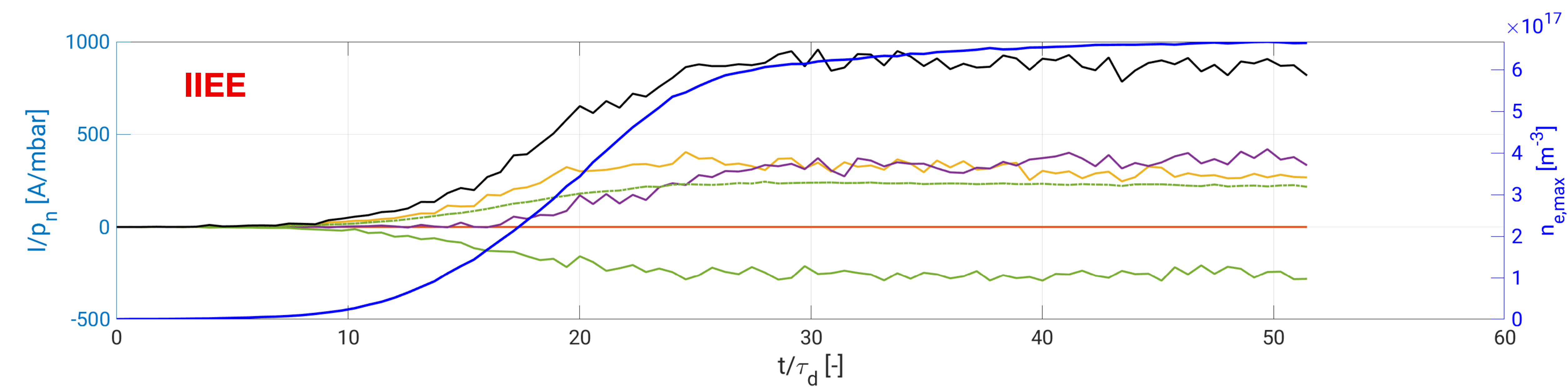
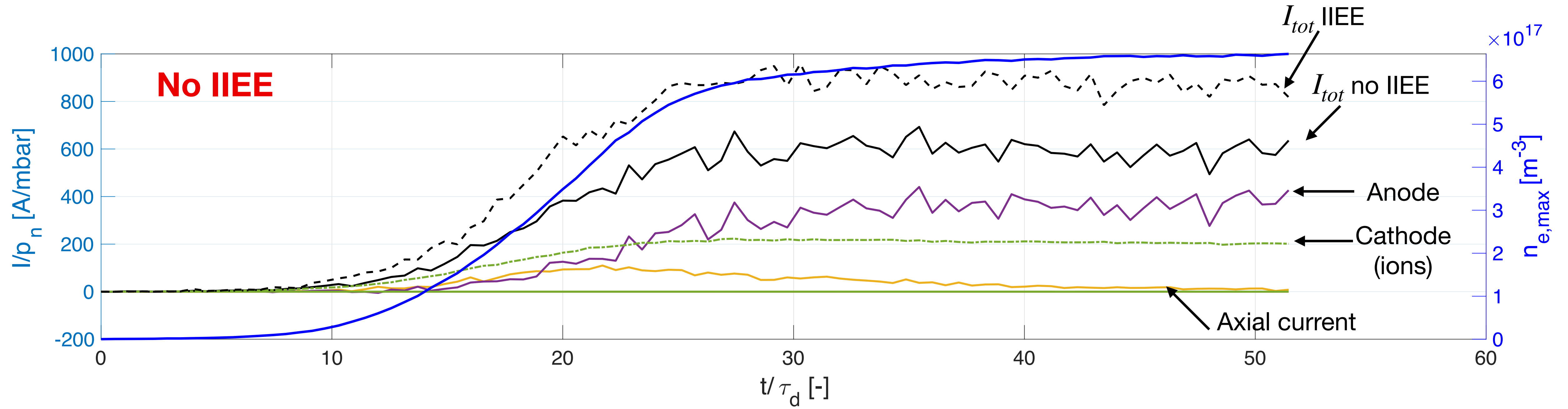
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EPFL TREX slanted - collected currents

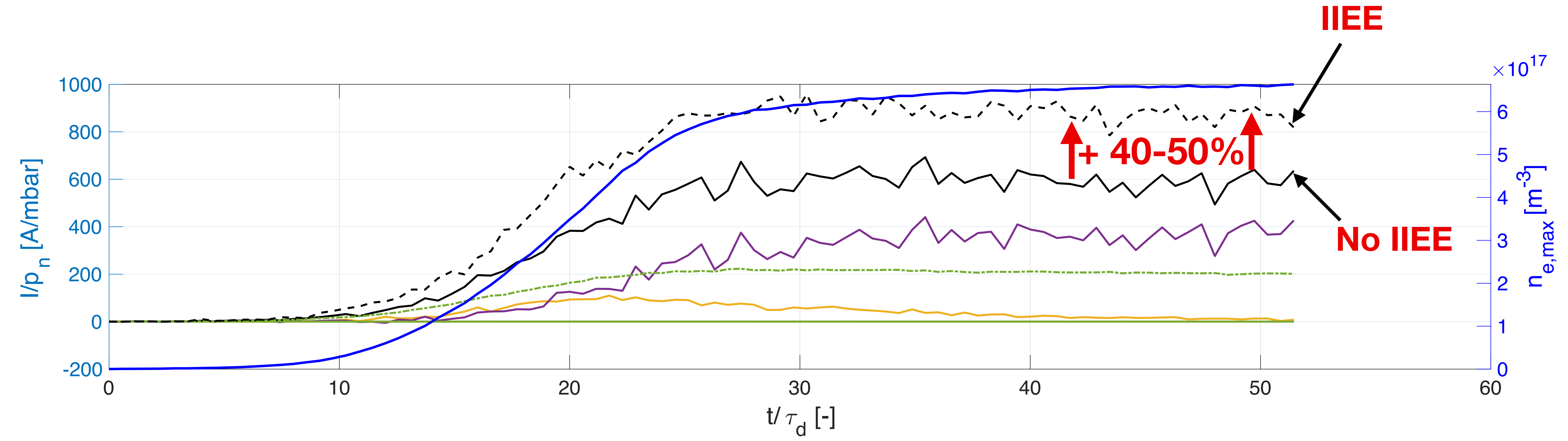


EPFL TREX slanted - collected currents



EPFL TREX slanted - SUMMARY

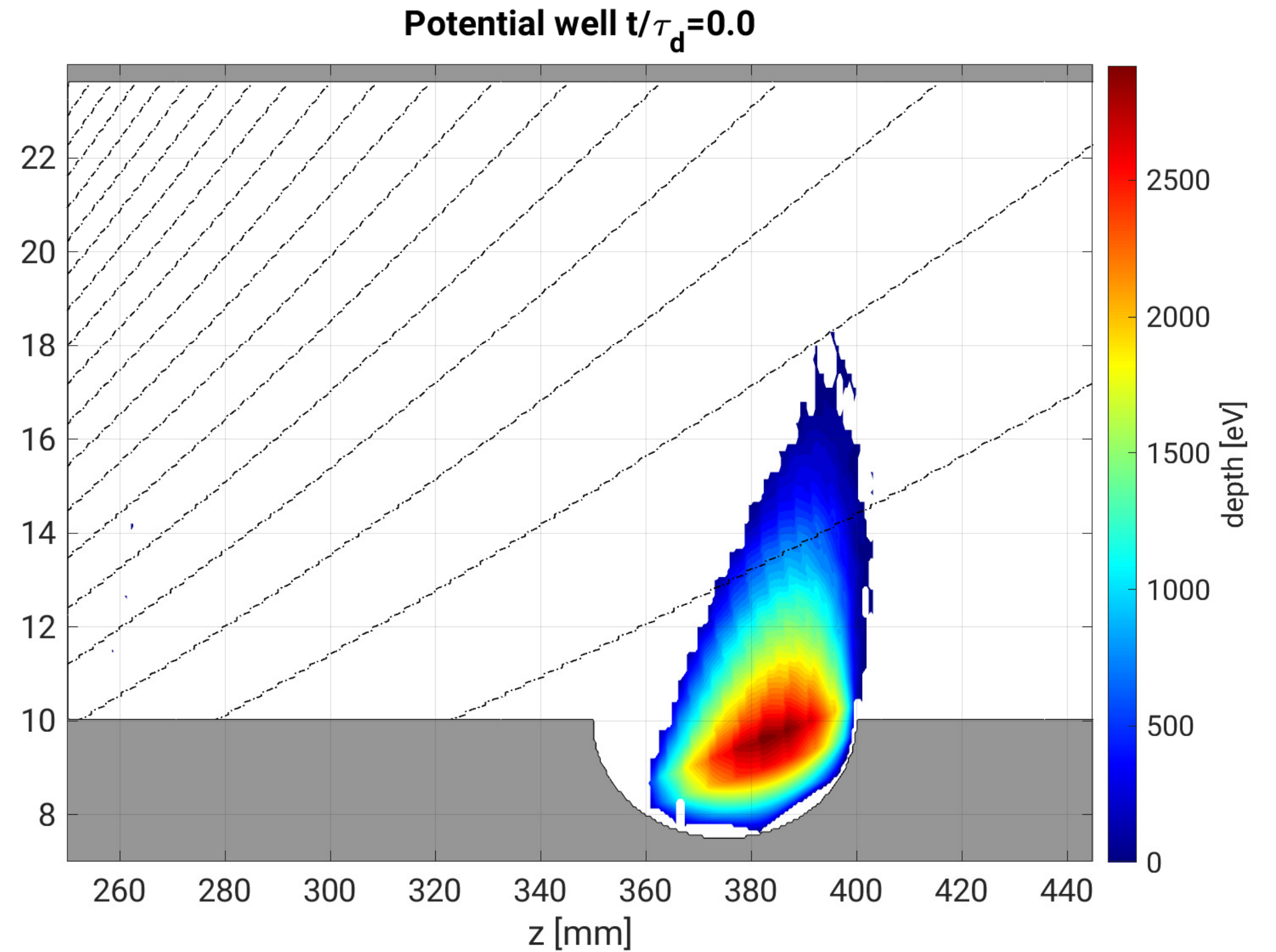
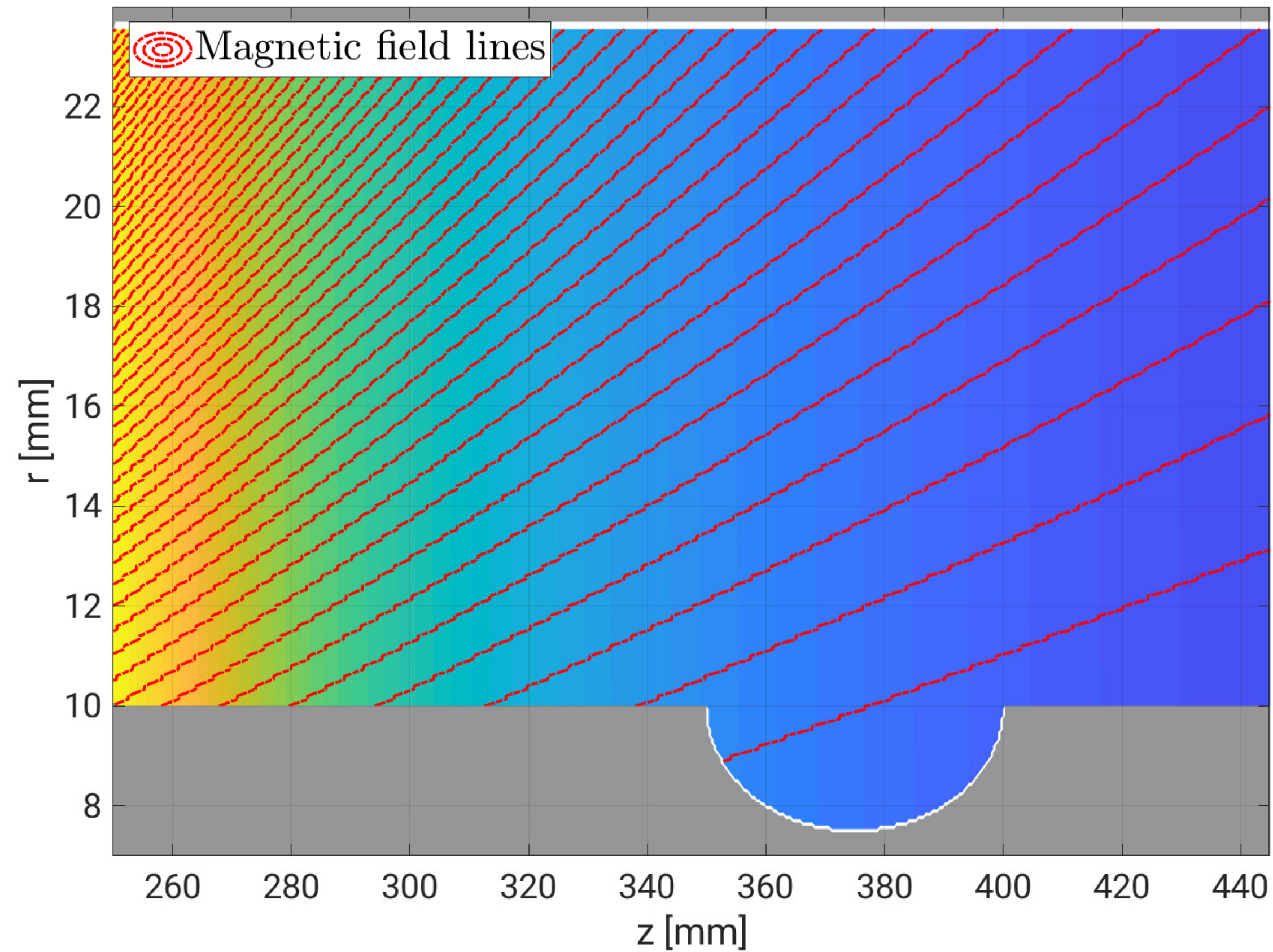
- Same cloud **densities**
- Same cloud **formation times**
- Current increased by \sim **40-50%**



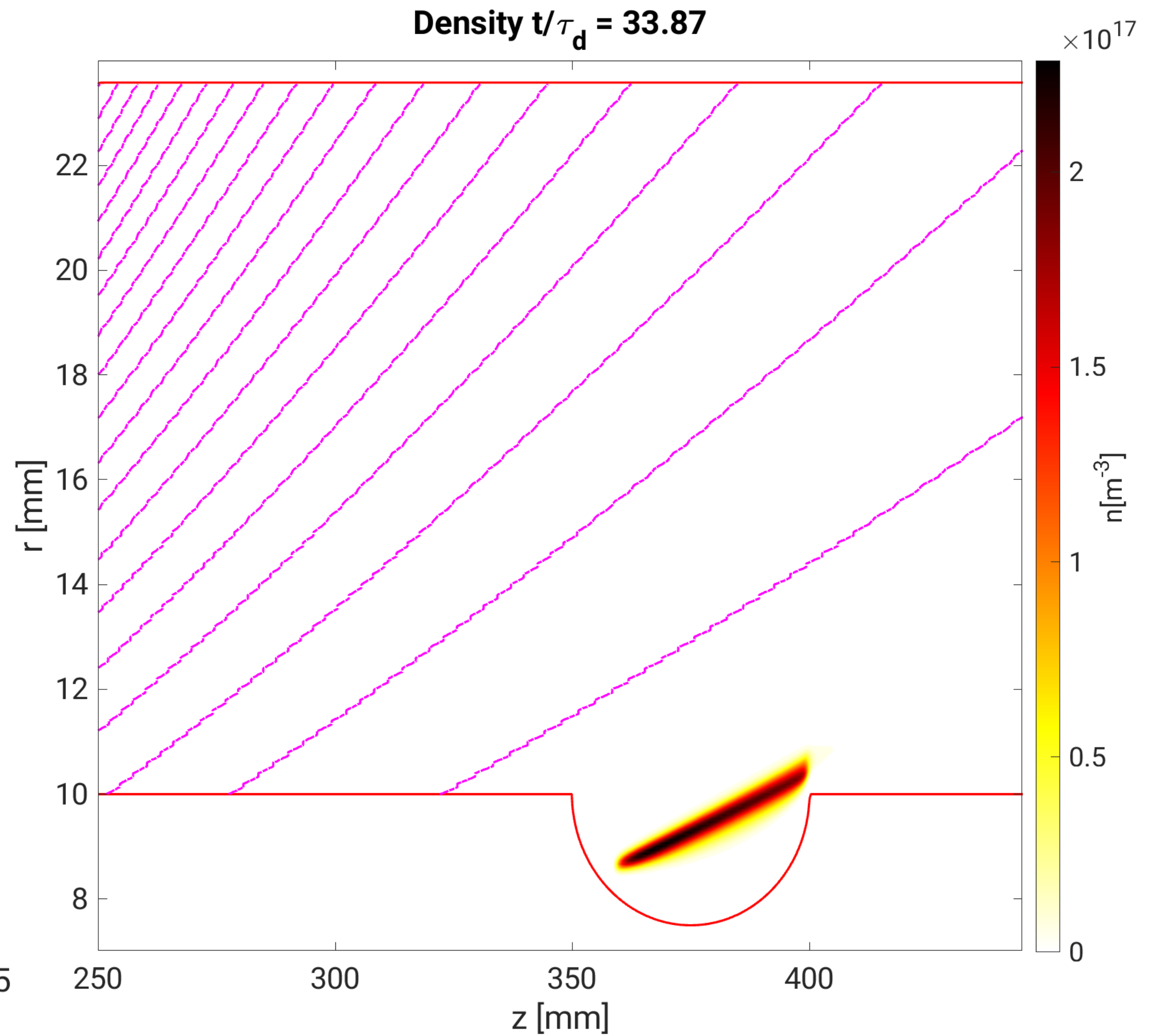
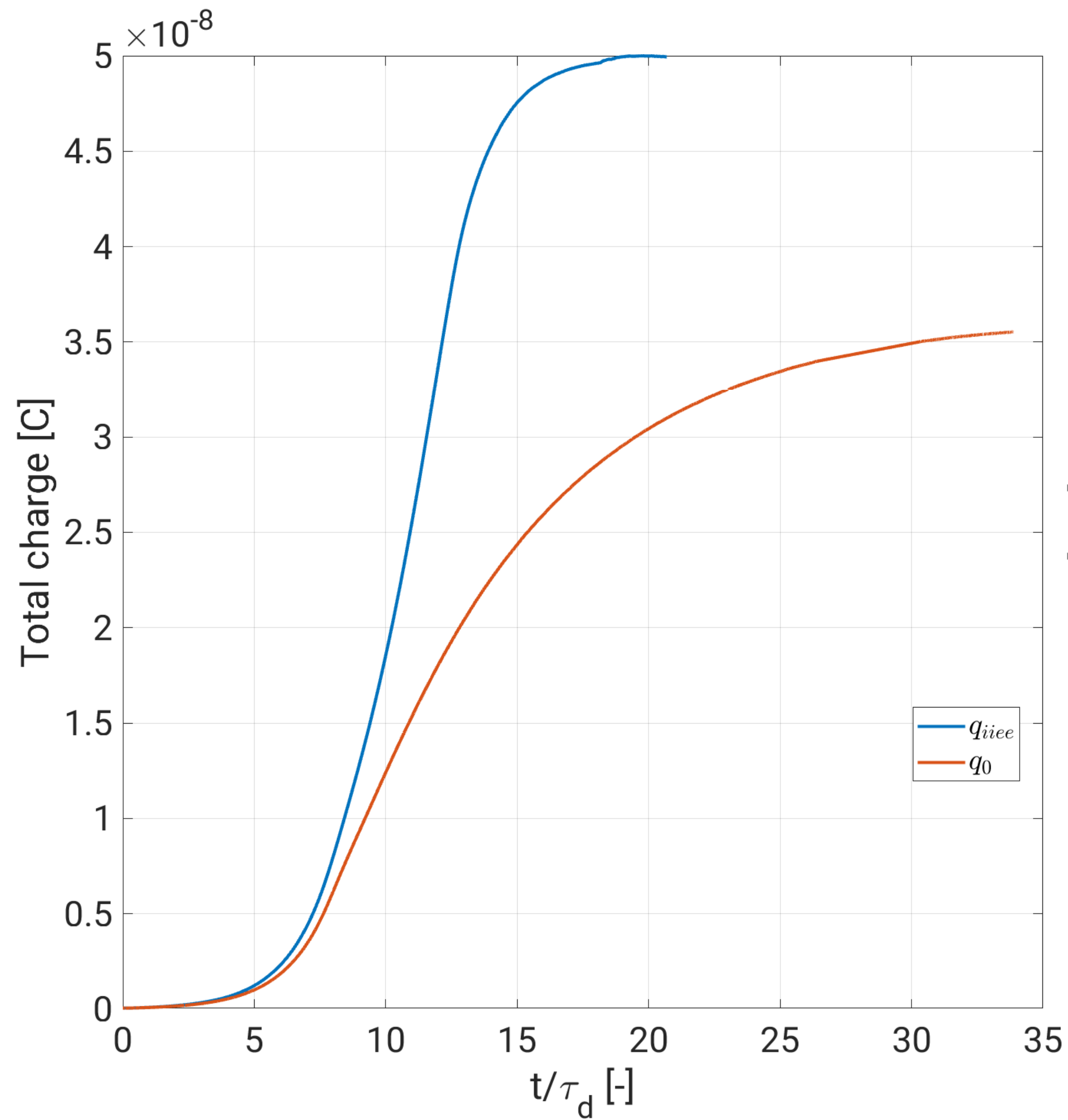
EPFL Cloud formation and dynamics: TRES extrude geometry

- Physical/numerical parameters

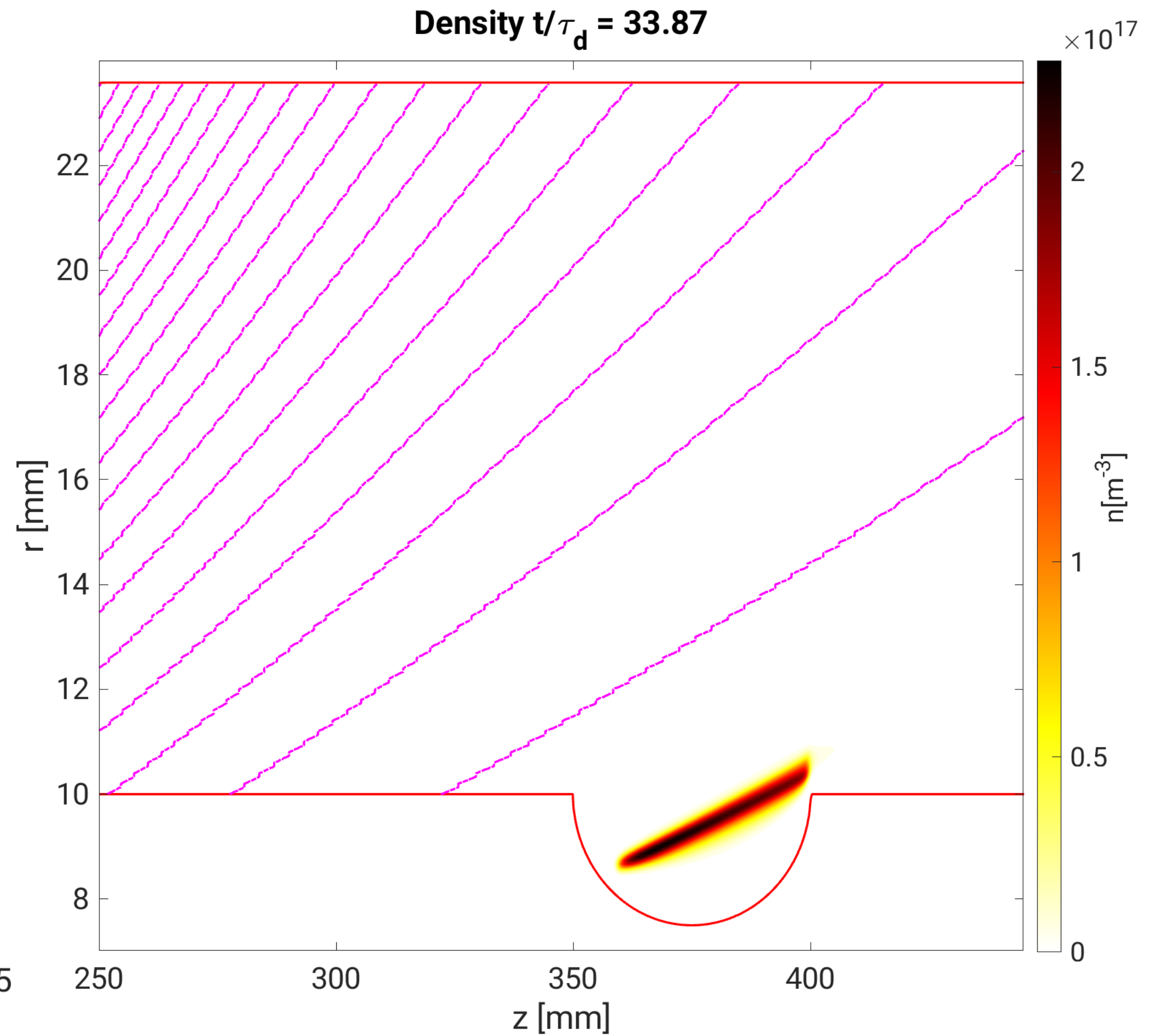
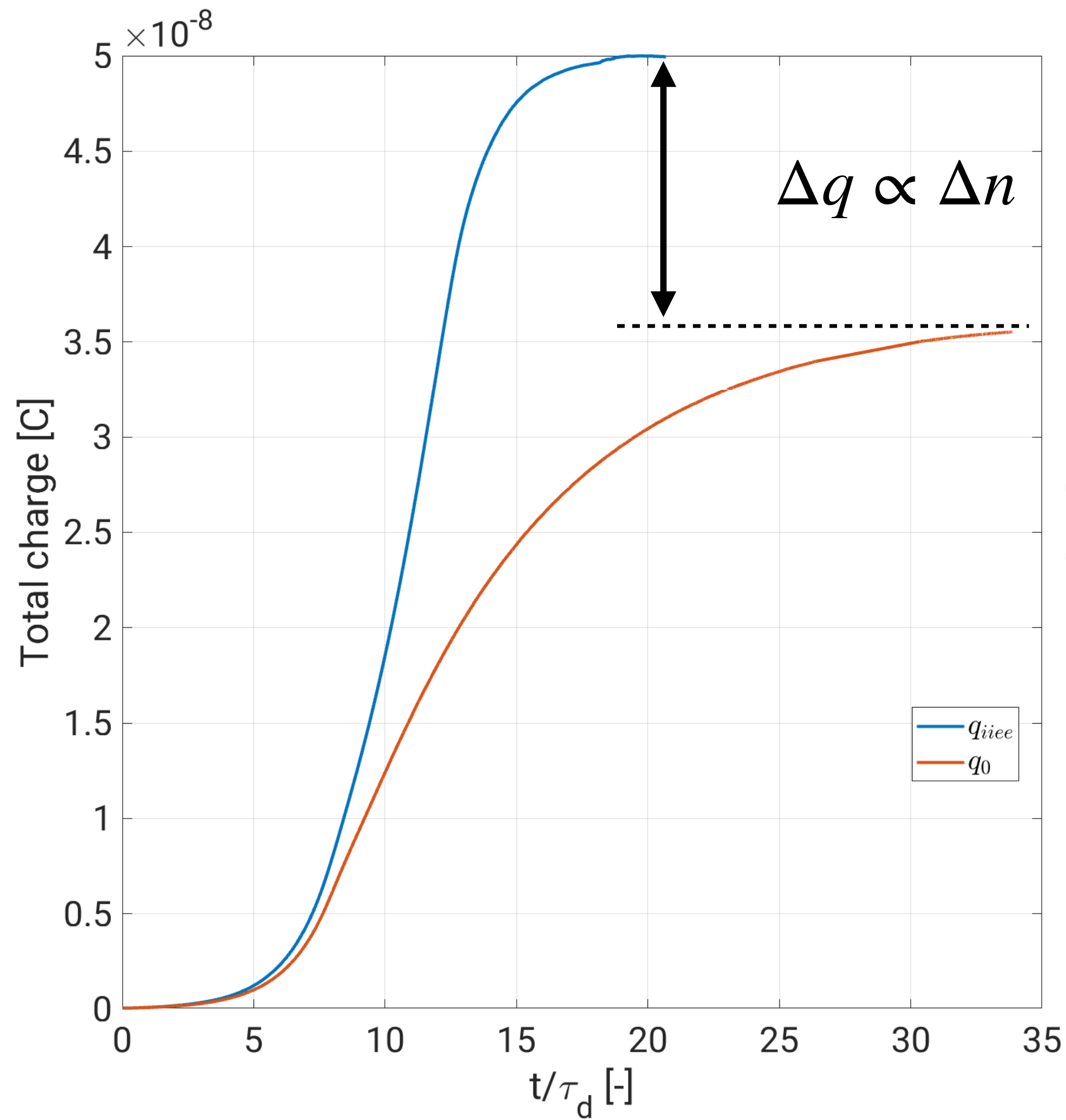
- $\Delta\Phi = 20$ kV
- Neutral pressure $P_n \sim 1 \cdot 10^{-2}$ mbar



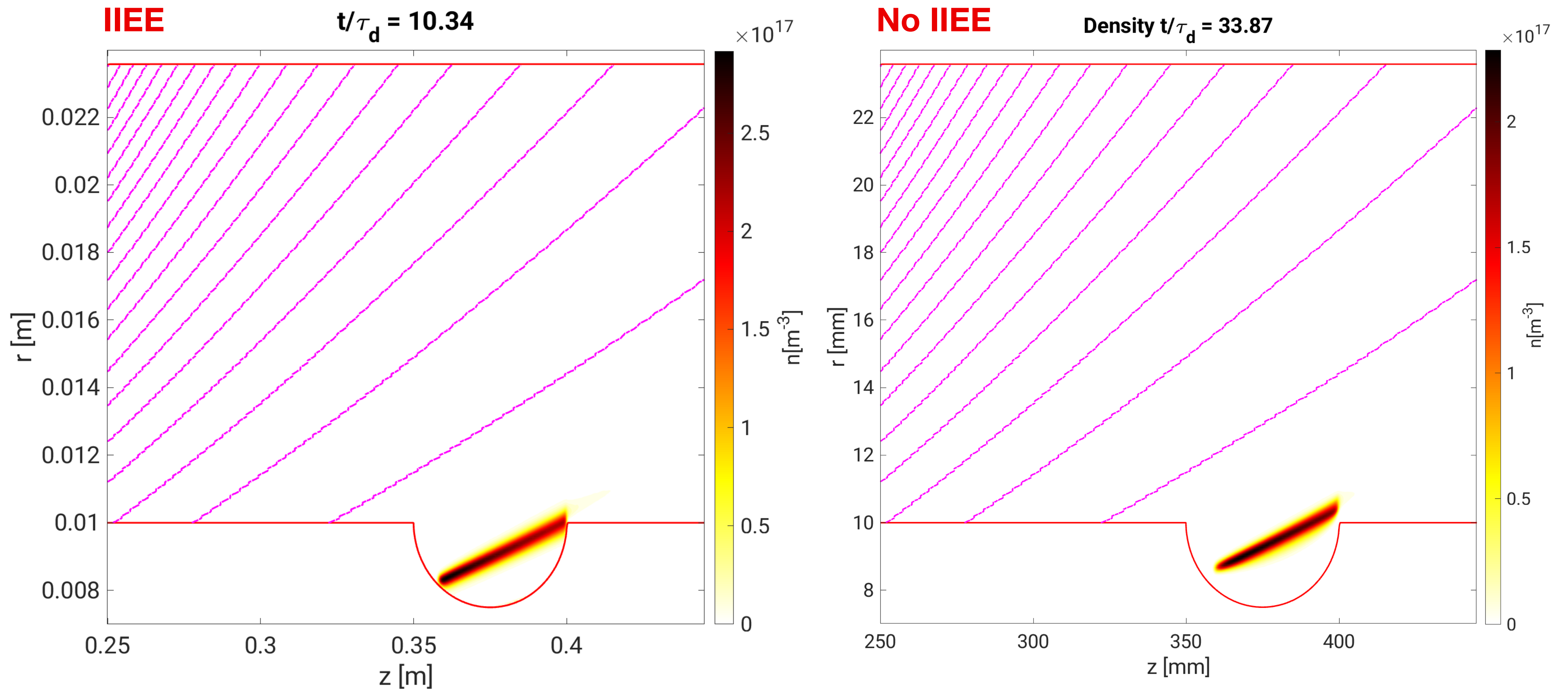
EPFL TREX extrude geometry - total charge and cloud formation



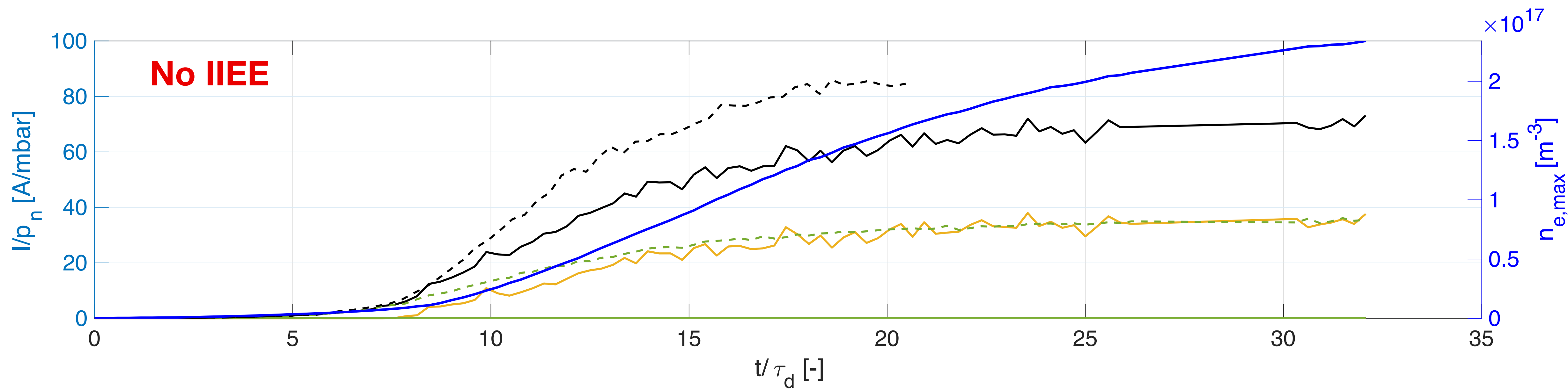
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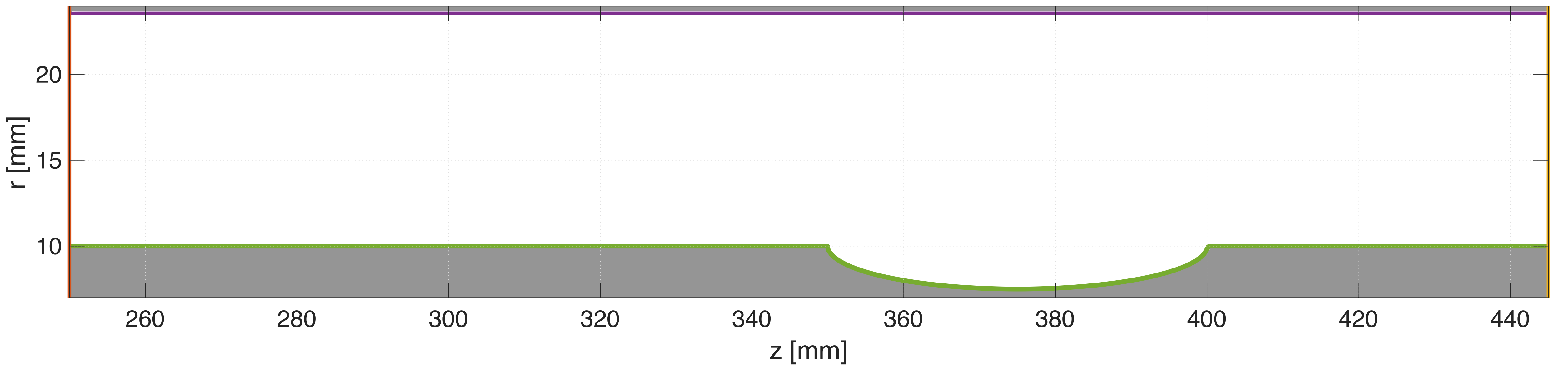
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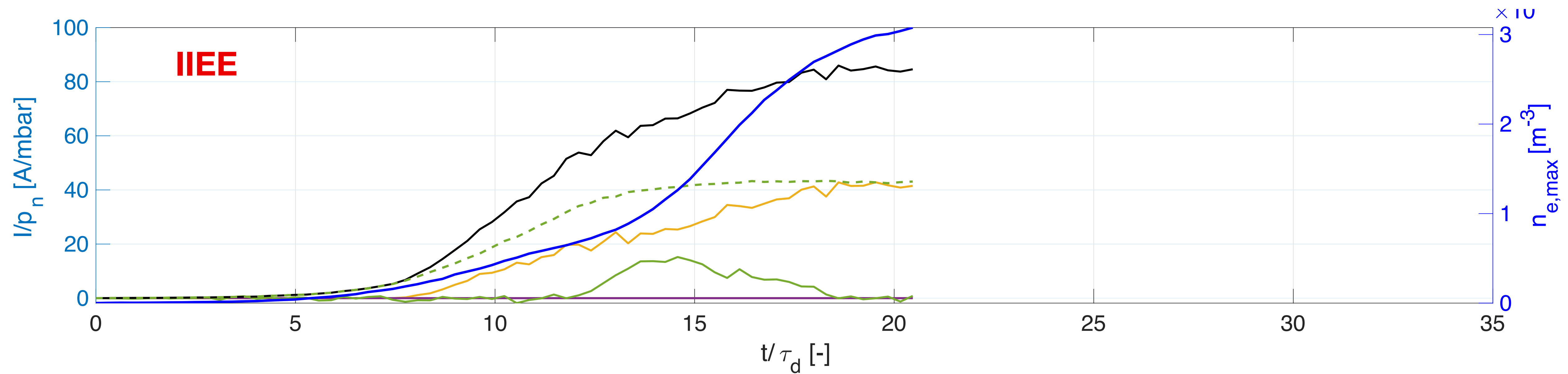
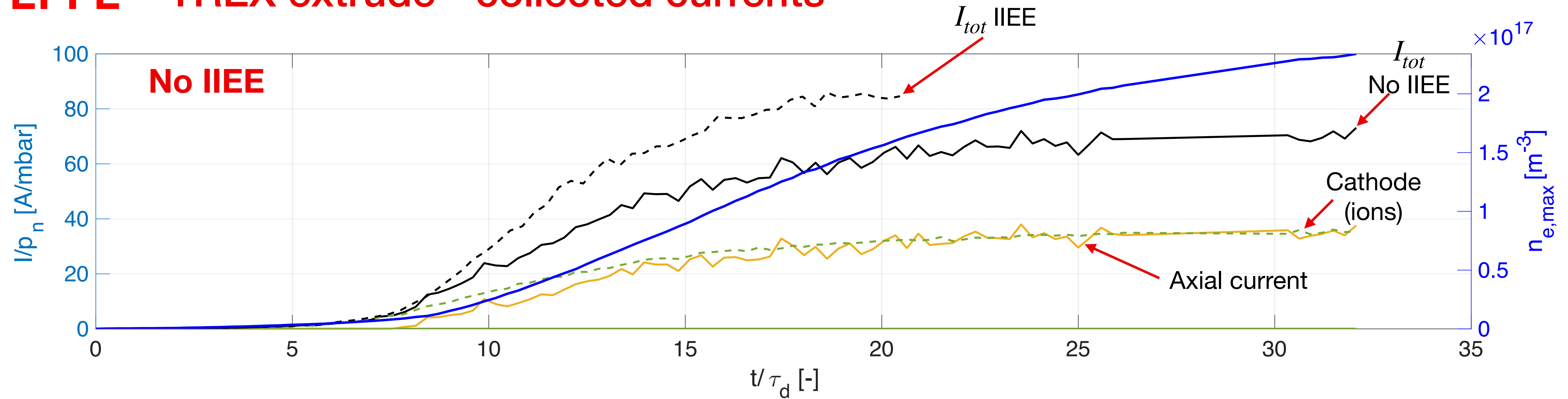
EPFL TREX extrude - collected currents



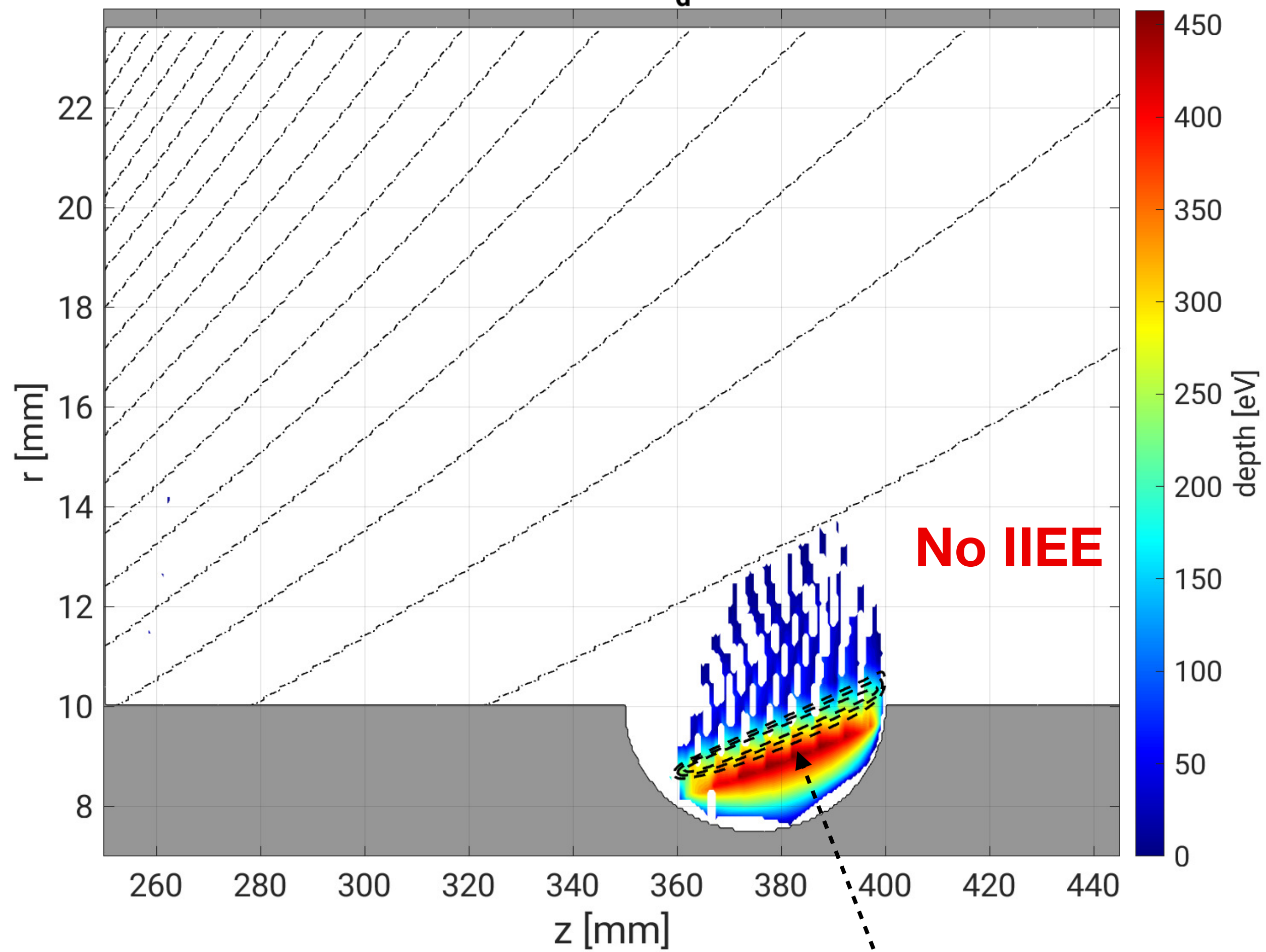
Domain



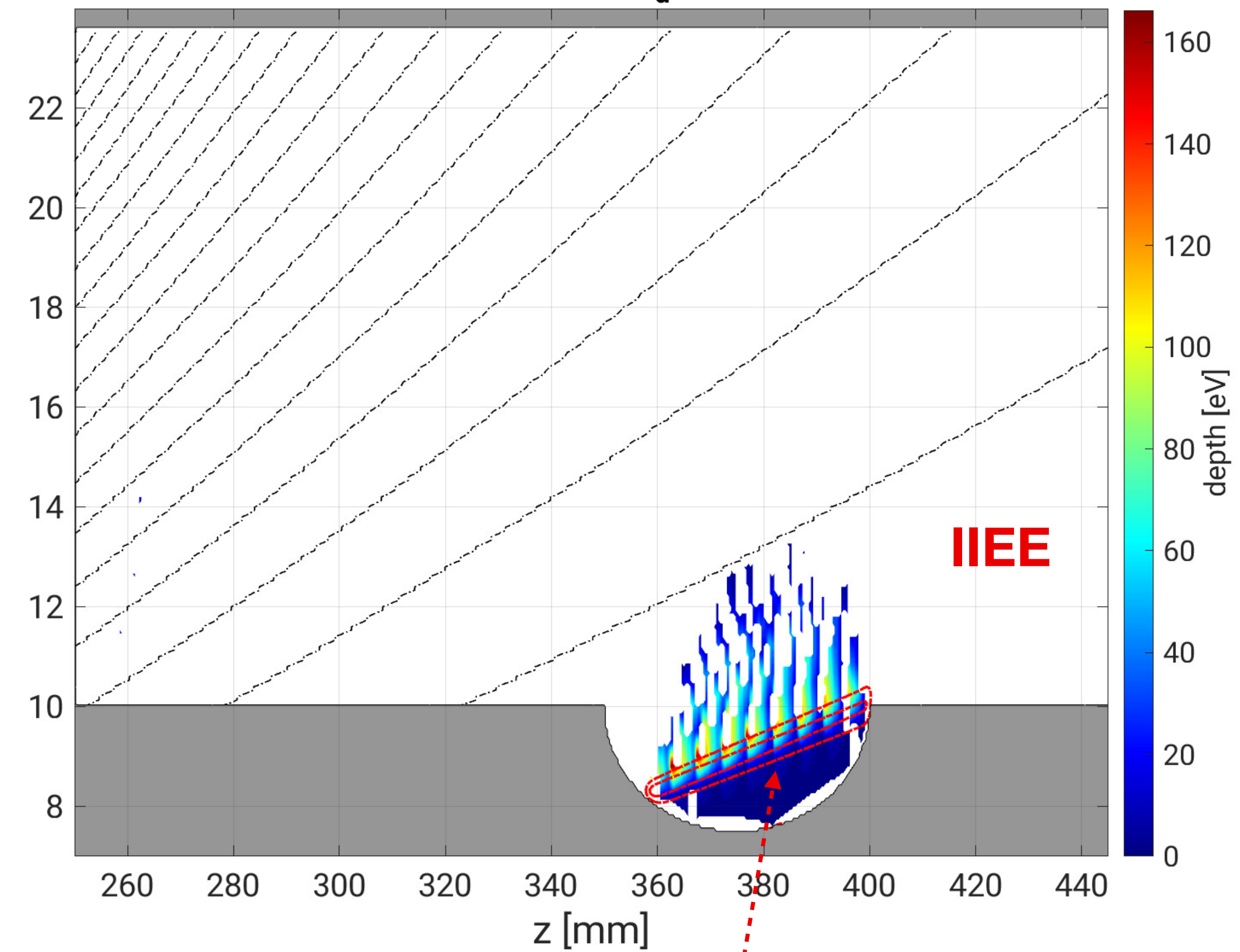
EPFL TREX extrude - collected currents



Potential well $t/\tau_d = 32.10$



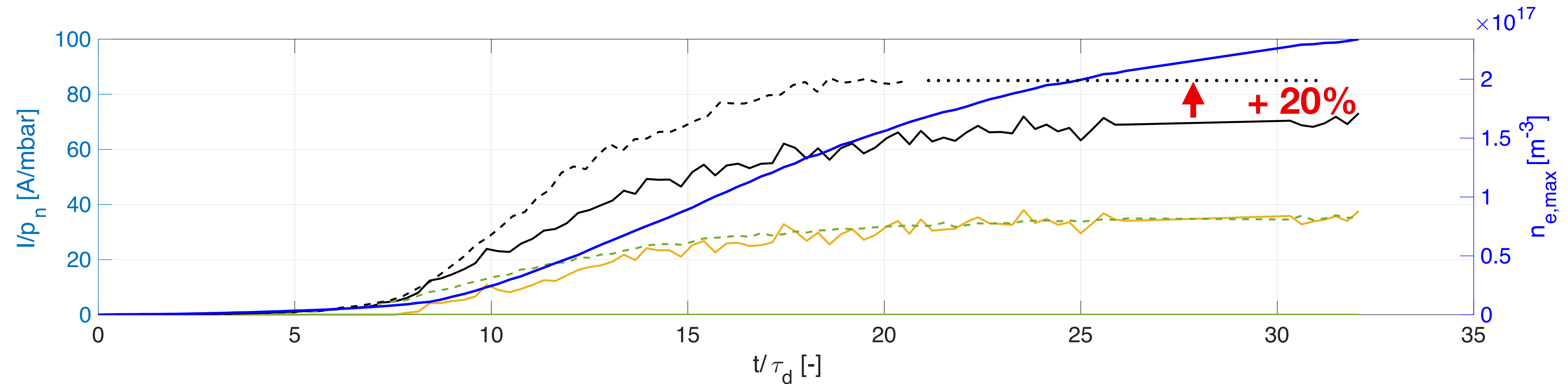
Potential well $t/\tau_d = 20.69$



Cloud located higher

Cloud located lower

- Density increased by IIEE of 20%
- Cloud forming about 3 times faster
- Current increased by \sim **20%**
- Cloud radially lower: well fills by bottom (IIE)

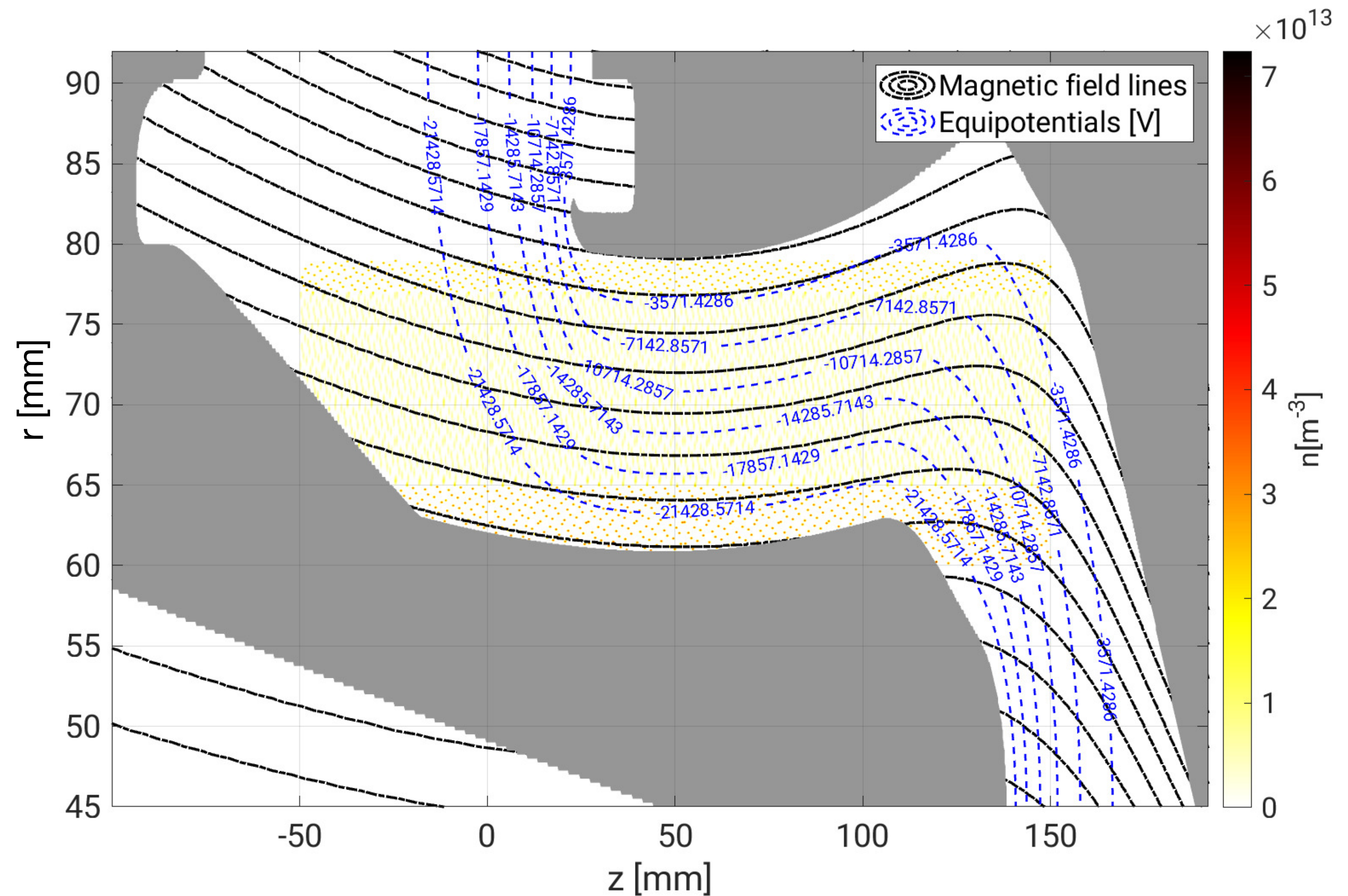


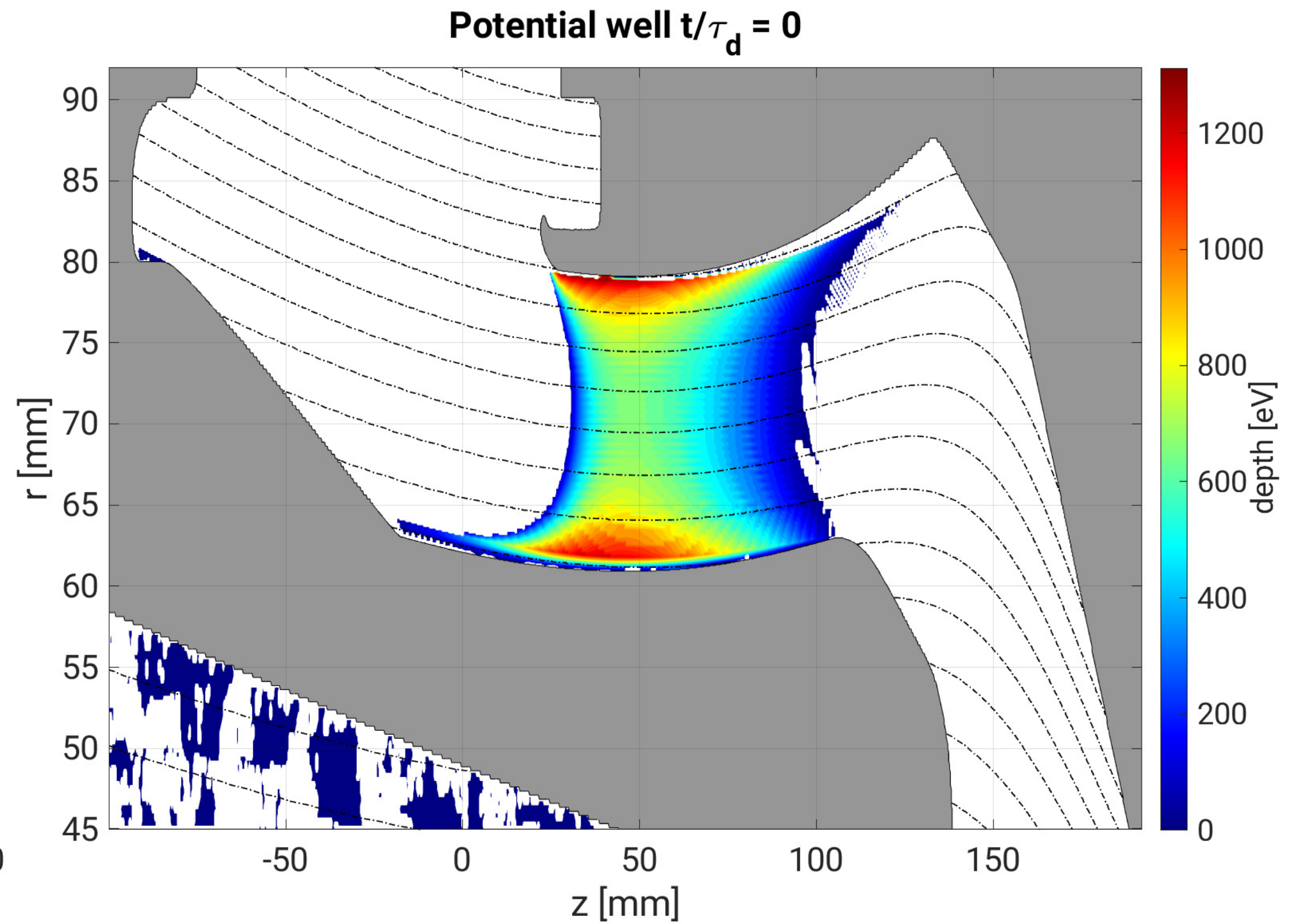
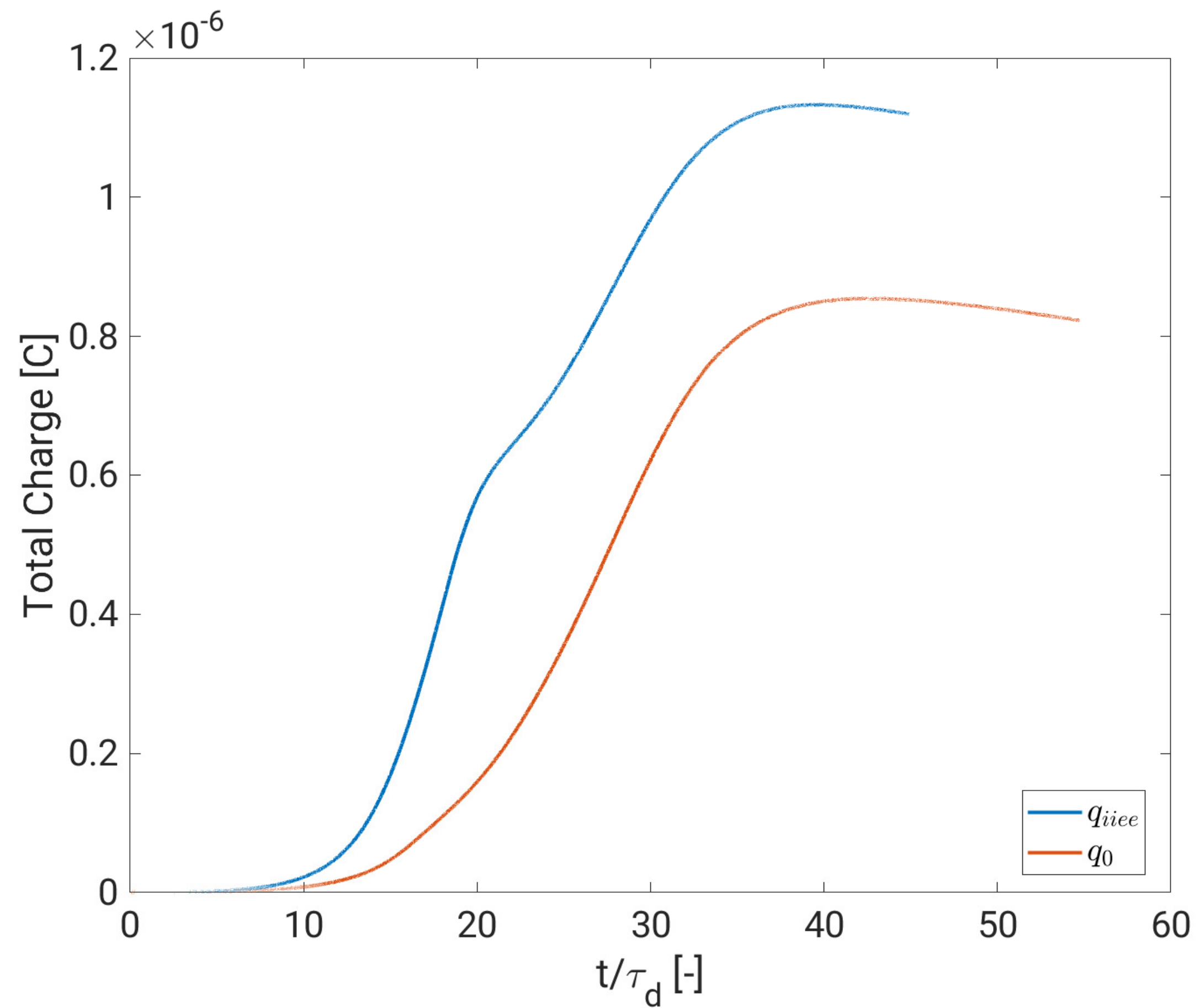
- Physical parameters

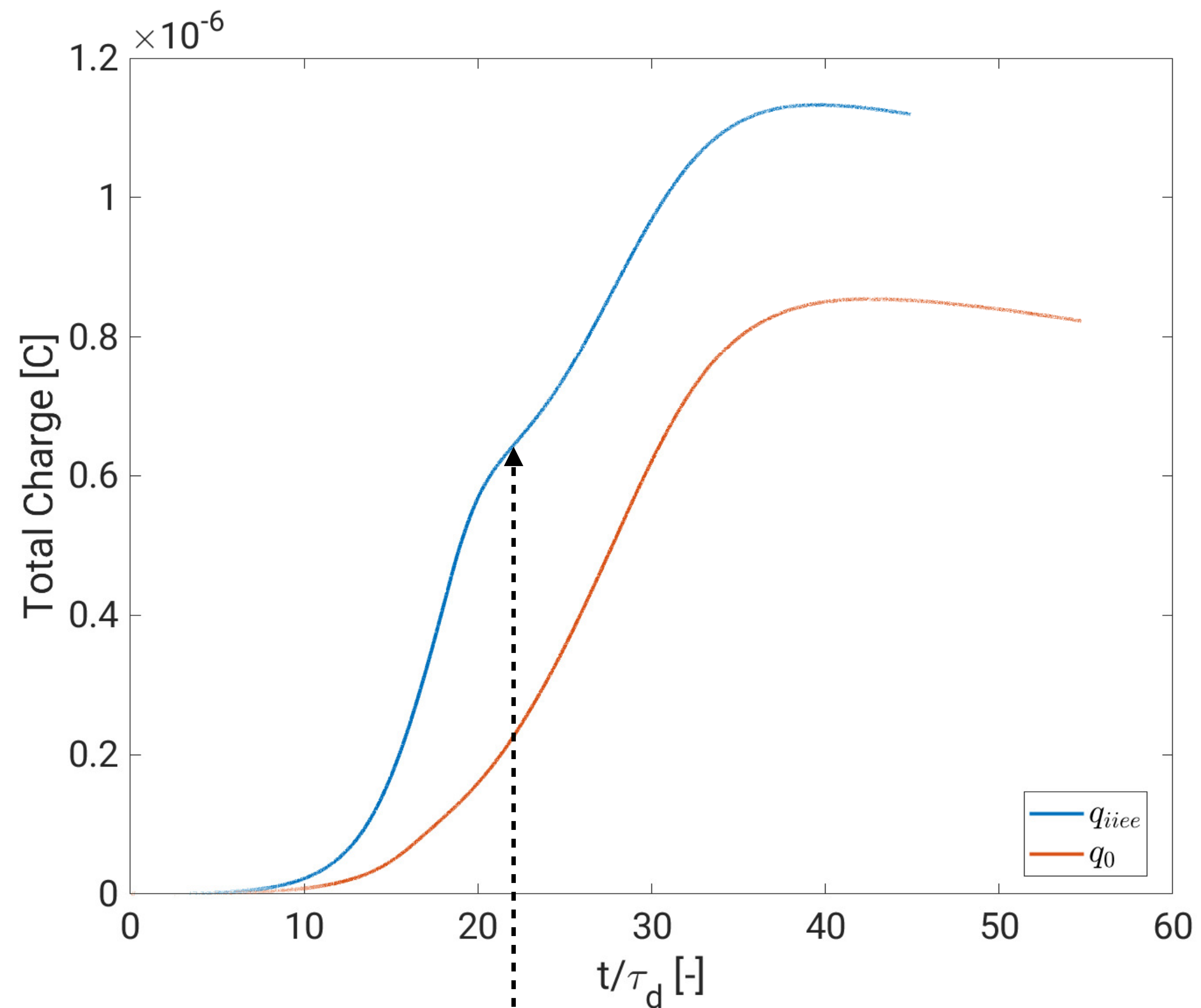
- $\Delta\Phi = 25 \text{ kV}$

- Neutral pressure
 $P_n \sim 2 \cdot 10^{-2} \text{ mbar}$

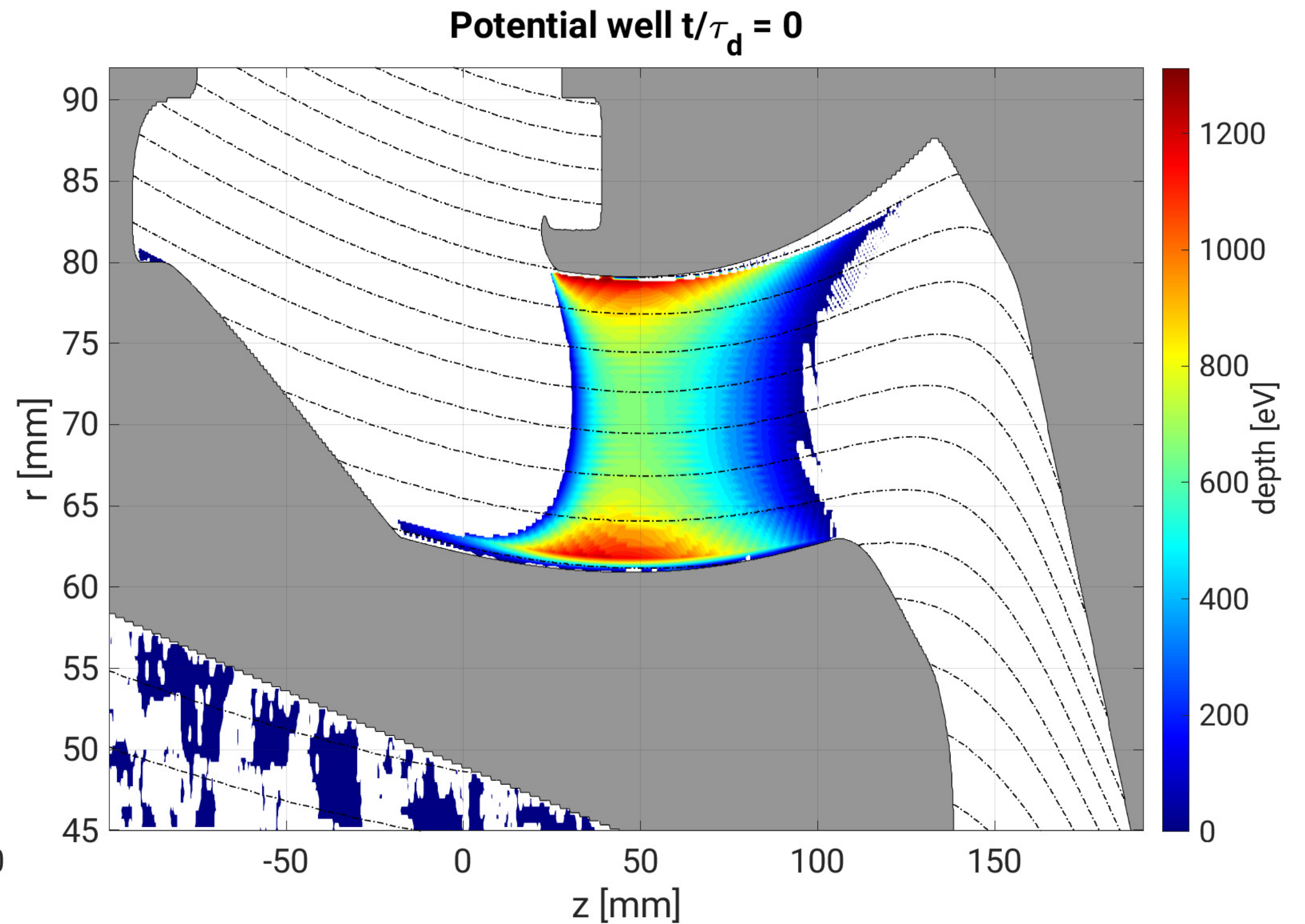
- 2 potential wells formed by equipotentials and magnetic field lines



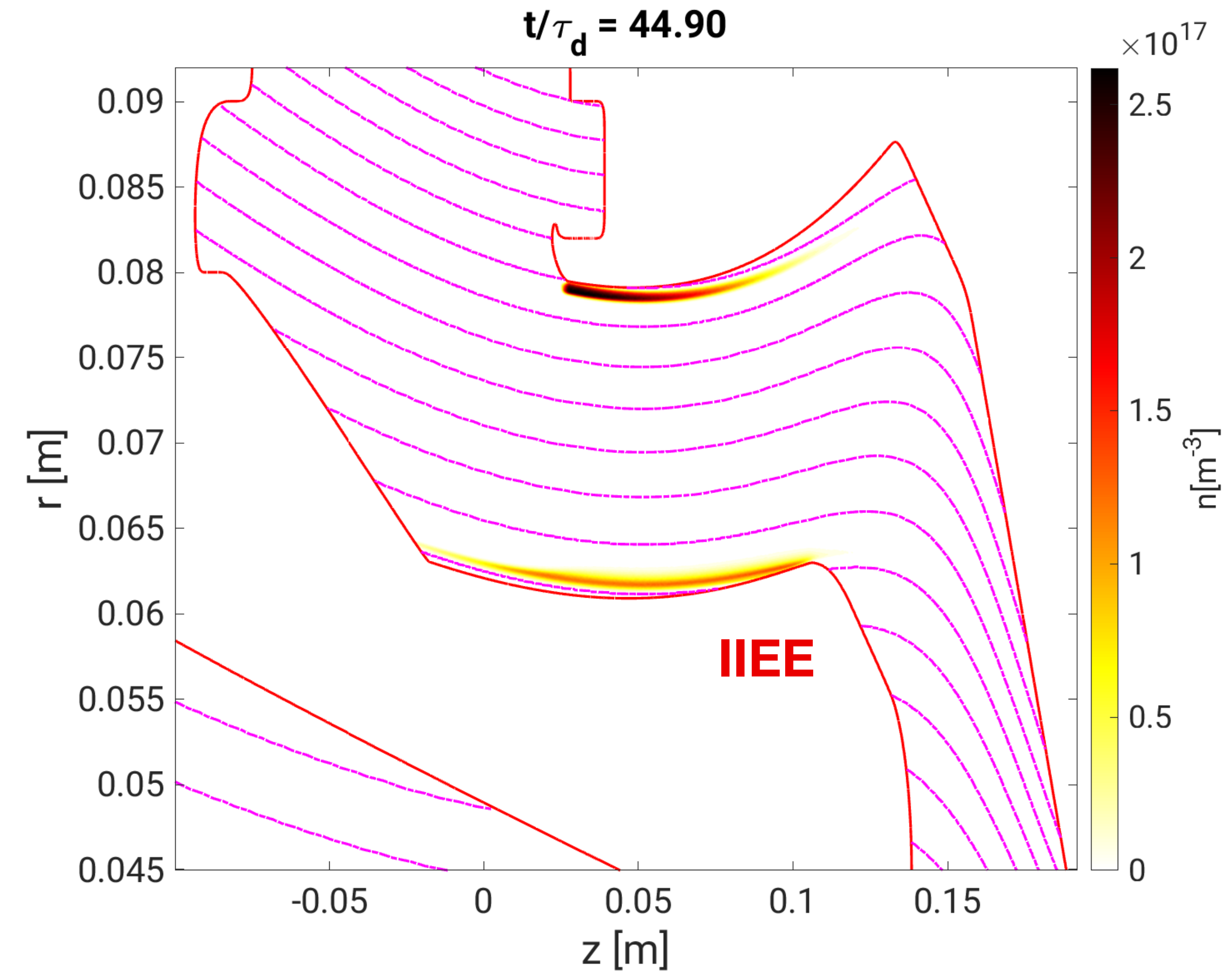
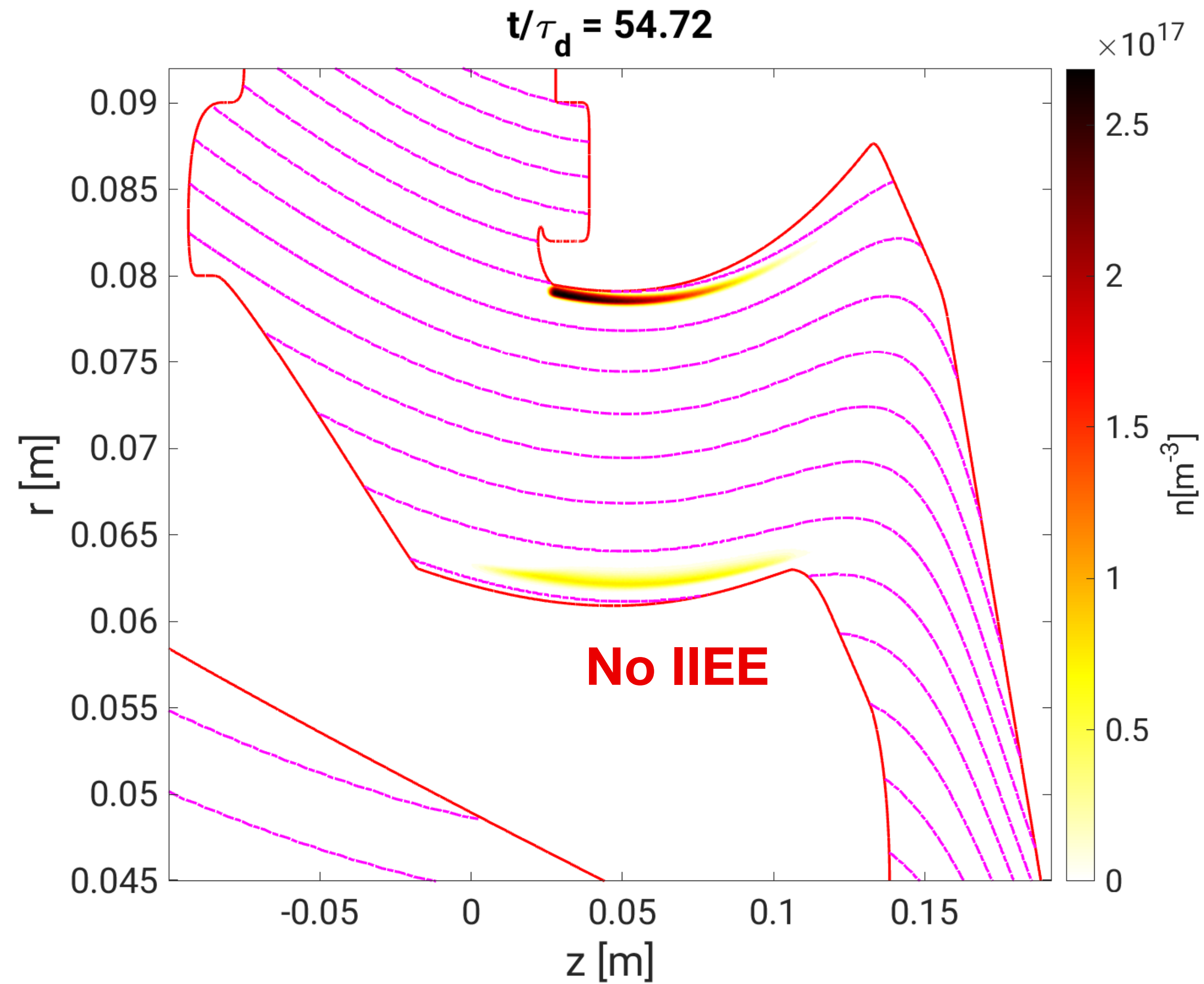




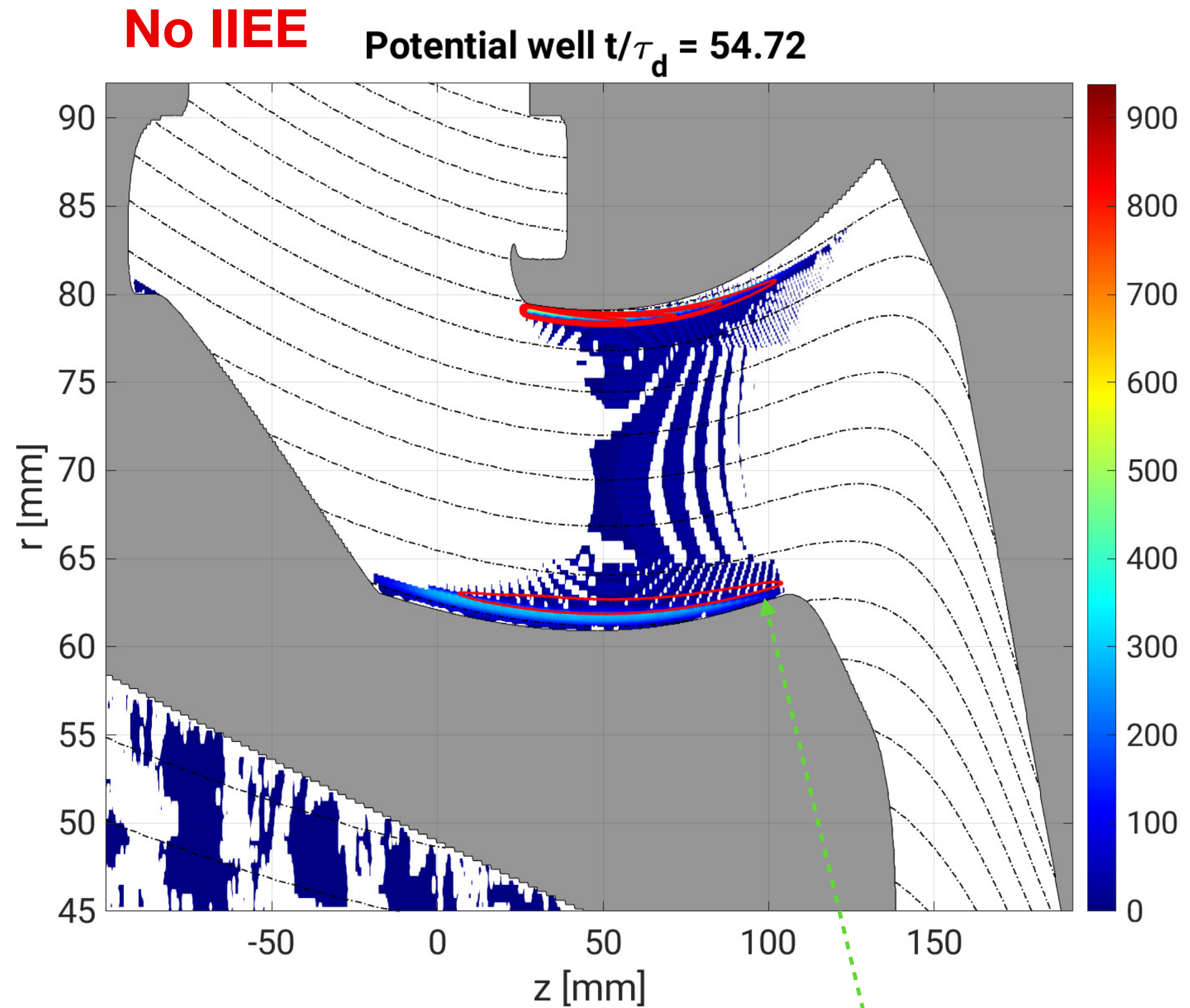
Bottom cloud filled first by IIE



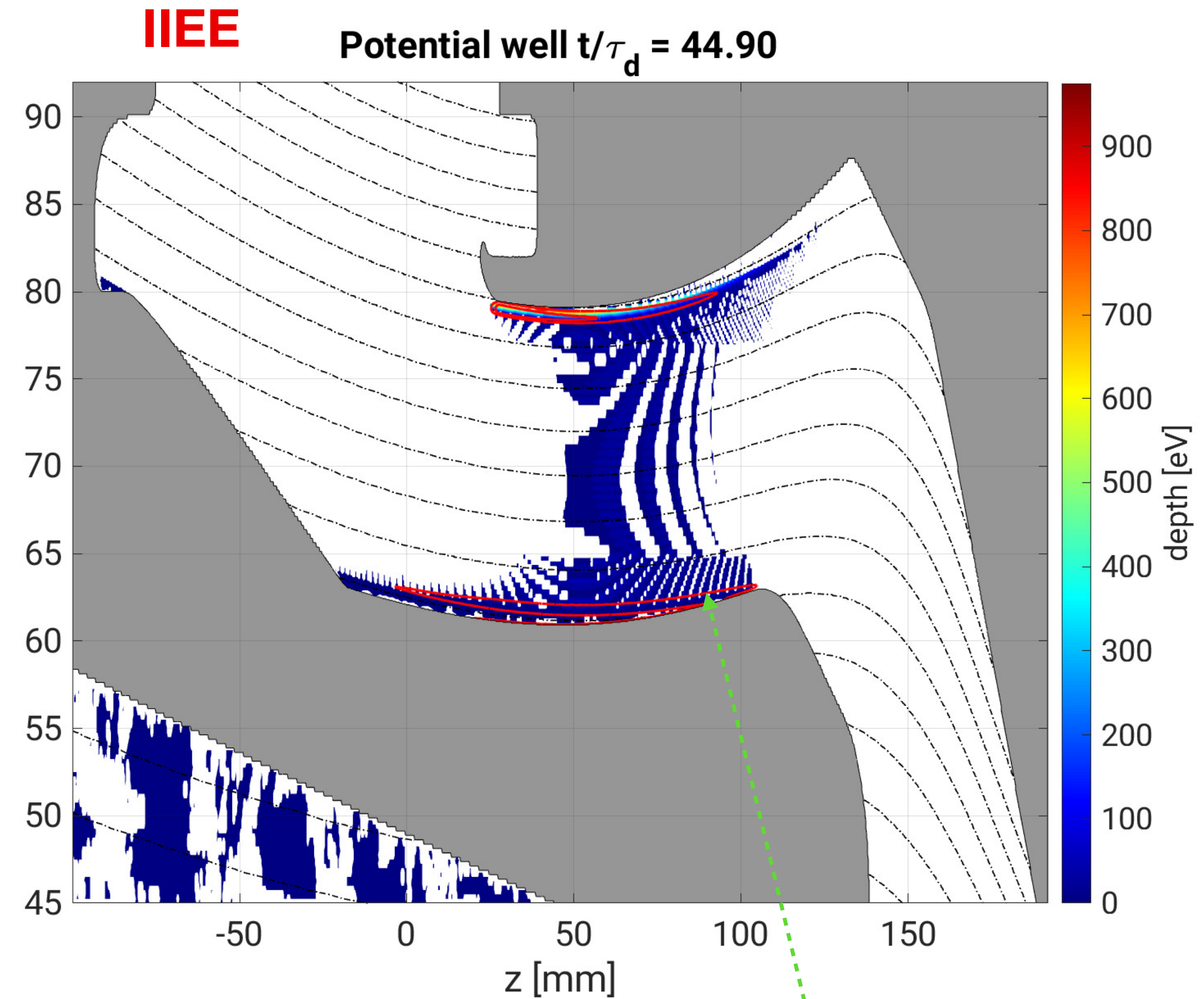
Gt-170: Final densities (both)



EPFL Gt-170: potential well and cloud contours

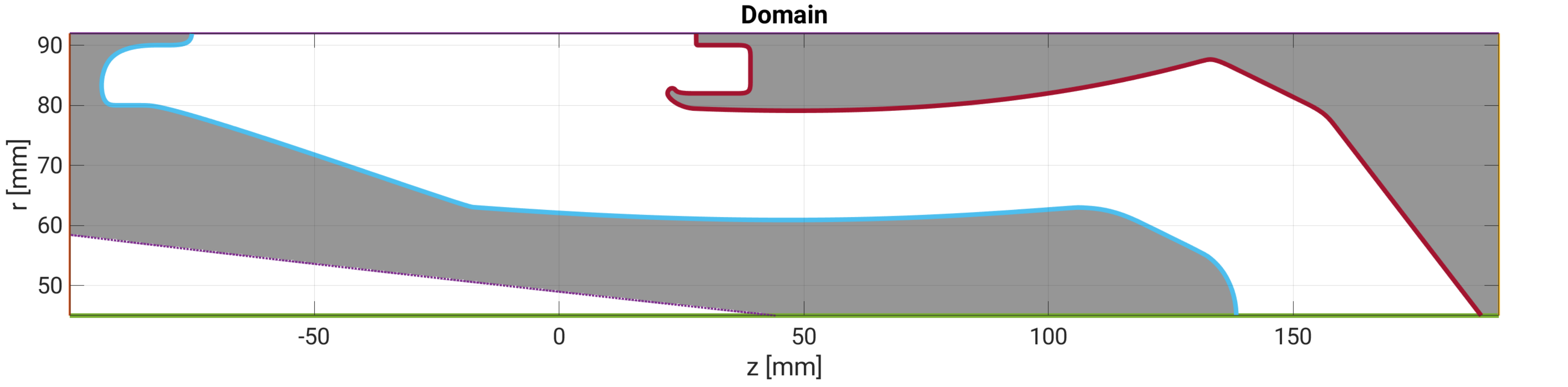
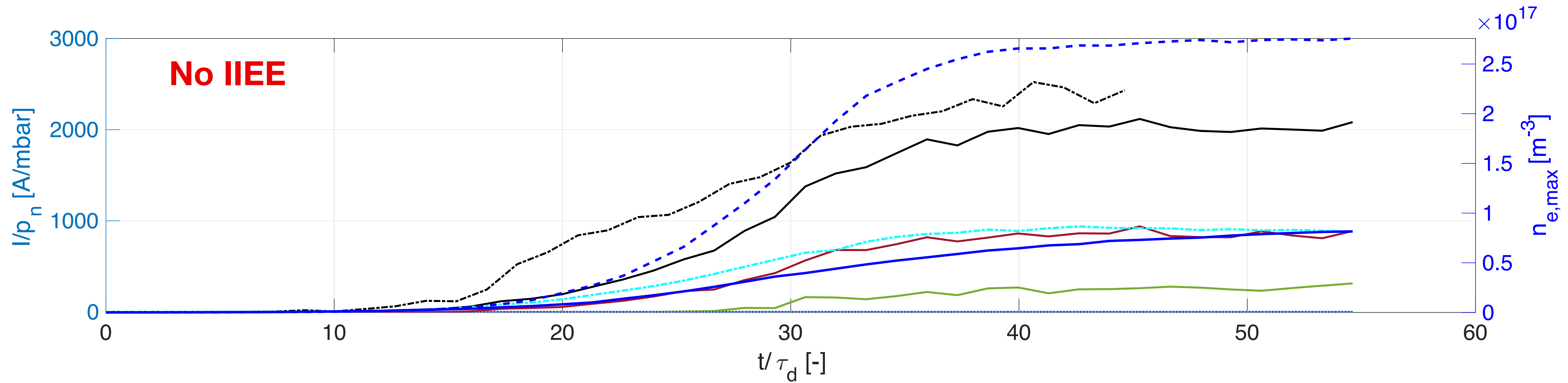


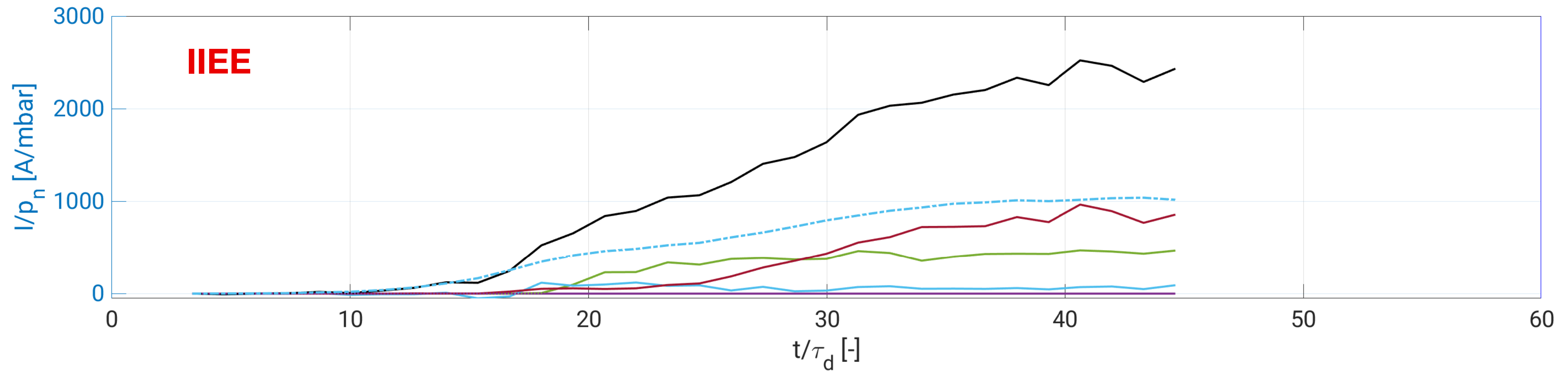
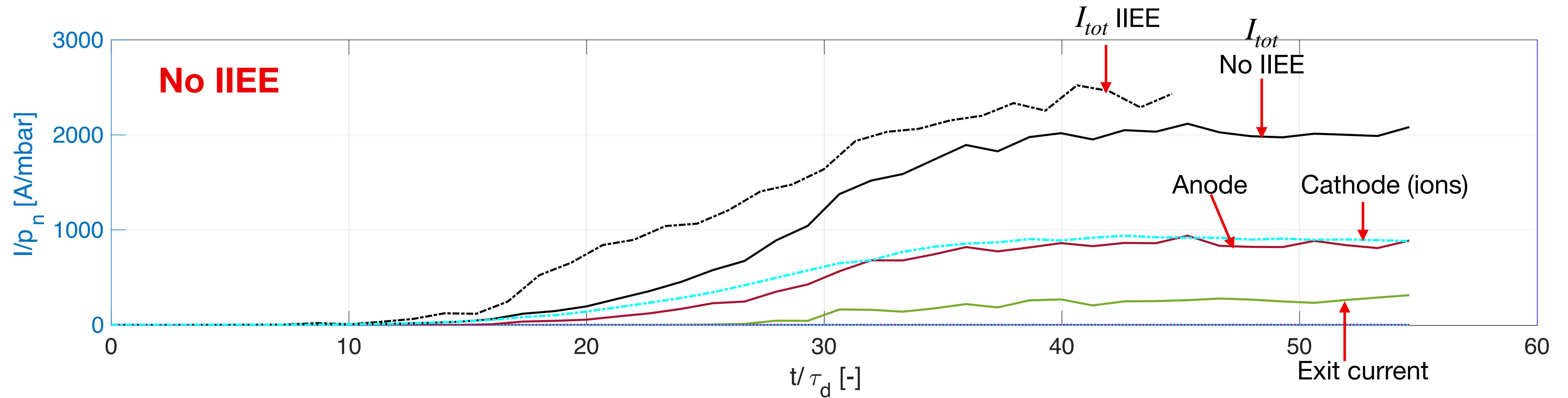
**Bottom cloud
located higher
(See TREX extrude)**

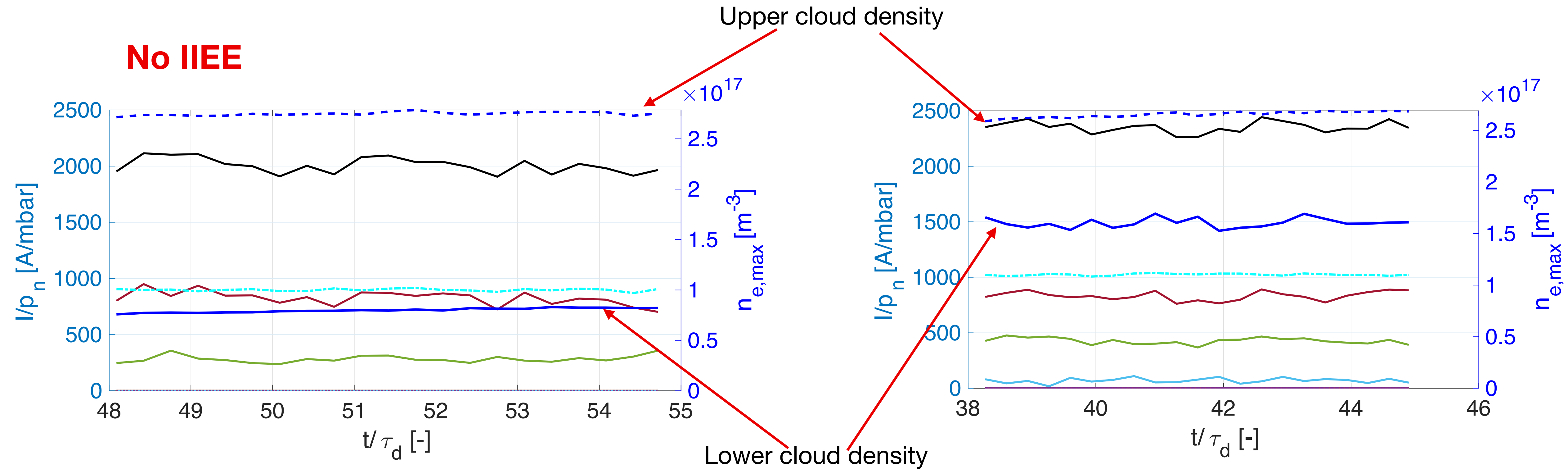


**Bottom cloud
located lower
(See TREX extrude)**

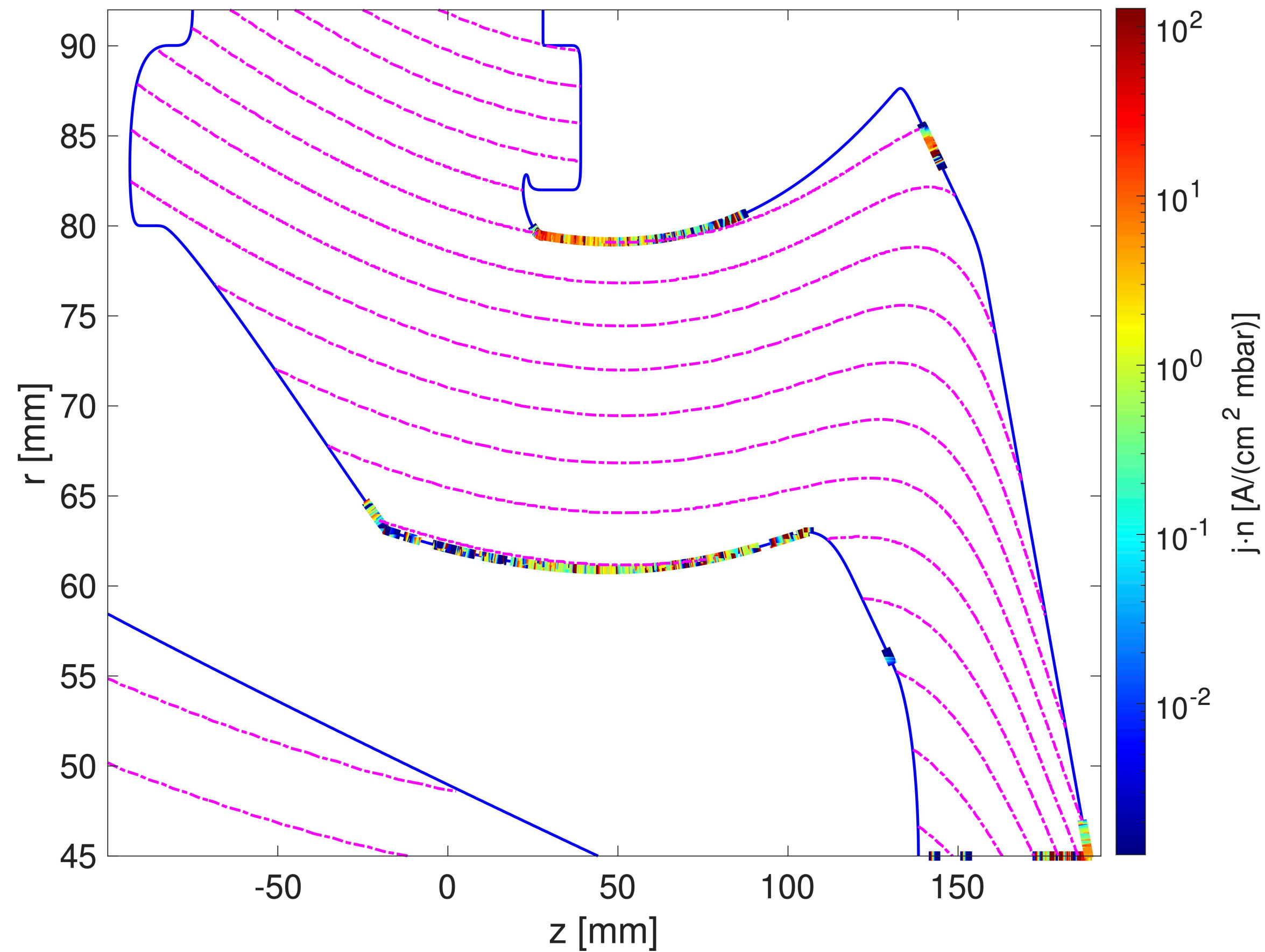
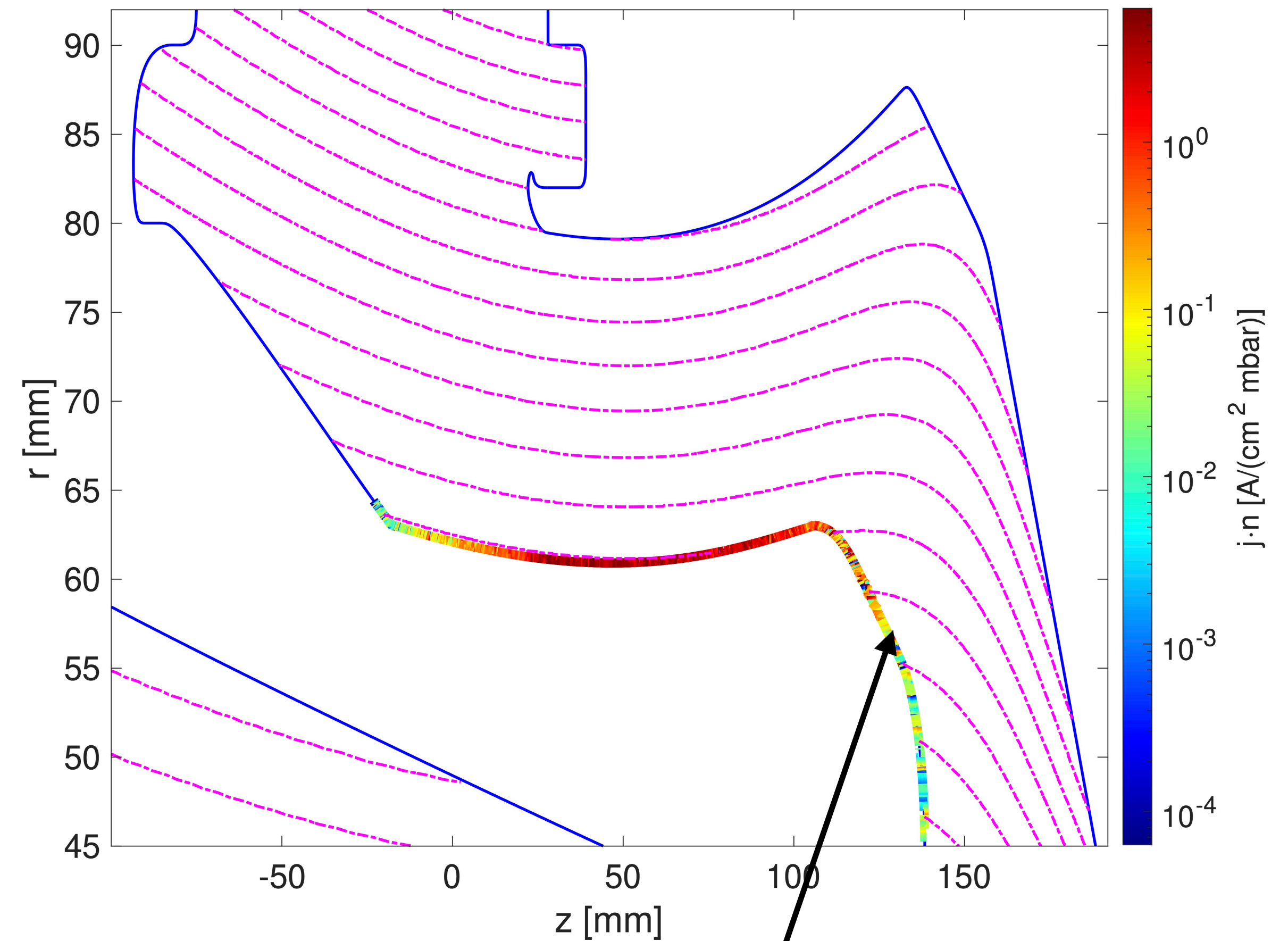
EPFL Gt-170: collected currents (No IIEE)







- Total current increased by about 20-25% (current from bottom well weaker).
- Bottom cloud density 2 twice as high as without IIEE.

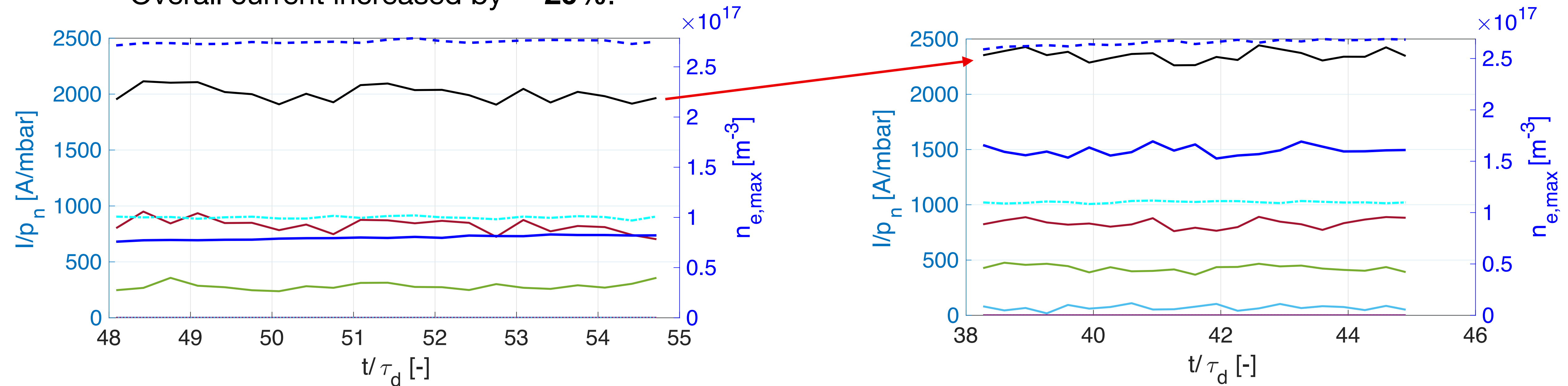
$t/\tau_d = 44.90$  $t/\tau_d = 44.90$ 

- Potentially adiabatically trapped electrons generated ?

Emission of possibly
adiab. trapped e^-

EPFL Gt-170: Summary

- Density doubled in lower well.
- Bottom cloud lower (radially) - See TRES results.
- Same behavior for upper cloud.
- TRES design is appropriate to describe this type of MIG.
- Overall current increased by \sim **20%**.



- TREX slanted and extrude geometry succeeded at predicting results in more general MIG geometries (see GT-170).
- Overall, the total current measured was affected by IIEE, increasing (on average) by 20%.
- However, still same order of magnitude.
- Bottom cloud density (only) affected.
- Potentially some non-desired effects induced: generation of adiabatically trapped electrons ?

[DS]: Davidson. *Physics of Non Neutral Plasmas*.

[LB22]: Guillaume Le Bars. *Models, manual and validations for FENNECS code*, 2022.

[Kis73]: L. M. Kishinevsky. *Estimation of electron potential emission yield on metal and ion parameters*.

[DH]: D. Hasselkamp. *Particle Induced Electron Emissions II*. Springer Berlin. Heidelberg

[PPZ+16]: I. Gr. Pagonakis et al. *Electron trapping mechanisms in Magnetron Injection Guns*. Physics of Plasmas, 2016.

[Cern]: *A remedy against electron clouds inside particle colliders*, home.cern (online)

Thank you !